LM339B, LM2901B, LM339, LM239, LM139, LM2901 Quad Differential Comparators

1 Features

- NEW LM339B and LM2901B
- Improved specifications of B-version
  - Maximum rating: up to 38 V
  - ESD rating (HBM): 2k V
  - Low input offset: 0.37 mV
  - Low input bias current: 3.5 nA
  - Low supply-current: 200 µA per comparator
  - Faster response time of 1 µsec
  - Extended temperature range for LM339B
- B-version is drop-in replacement for LM239, LM339 and LM2901, A and V versions
- Common-mode input voltage range includes ground
- Differential input voltage range equal to maximum-rated supply voltage: ±38 V
- Low output saturation voltage
- Output compatible with TTL, MOS, and CMOS
- For single version, see the TL331B
- For dual version, see the LM393B or LM2903B

2 Applications

- Vacuum robot
- Single phase UPS
- Server PSU
- Cordless power tool
- Wireless infrastructure
- Applicances
- Building automation
- Factory automation & control
- Motor drives
- Infotainment & cluster

3 Description

The LM339B and LM2901B devices are the next generation versions of the industry-standard LM339 and LM2901 comparator family. These next generation B-version comparators feature lower offset voltage, higher supply voltage capability, lower supply current, lower input bias current, lower propagation delay, and improved 2 kV ESD performance and input ruggedness through dedicated ESD clamps. The LM339B and LM2901B can drop-in replace the LM239, LM339 and LM2901, for both "A" and "V" grades.

All devices consist of four independent voltage comparators that are designed to operate from a single power supply over a wide range of voltages.

Device Information

PART NUMBER	PACKAGE (1)	BODY SIZE (NOM)
LM139x	CDIP (14)	21.30 mm × 7.60 mm
LM139x, LM239x, LM339x, LM2901x, LM339B, LM2901B	SOIC (14)	8.70 mm × 3.90 mm
LM239, LM339x, LM2901	PDIP (14)	19.30 mm × 6.40 mm
LM239, LM2901, LM339B, LM2901B	TSSOP (14)	5.00 mm × 4.40 mm
LM339x, LM2901, LM339B, LM2901B	SO (14)	10.20 mm × 5.30 mm
LM339x, LM339B	SSOP (14)	6.50 mm × 5.30 mm
LM2901B	SOT-23 (14)	4.20 mm x 2.00 mm
	WQFN (16)	3.00 mm x 3.00 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Family Comparison Table

Specification	LM339B	LM2901B	LM339 LM339A	LM2901 LM2901A	LM2901V LM2901AV	LM139 LM139A	LM239 LM239A	Units
Supply Voltage	2 to 36	2 to 36	2 to 30	2 to 30	2 to 32	2 to 30	2 to 30	V
Total Supply Current (5V to 36V max)	0.8 to 1	0.8 to 1	1 to 2.5	1 to 2.5	1 to 2.5	1 to 2.5	1 to 2.5	mA
Temperature Range	−40 to 85	−40 to 125	0 to 70	−40 to 125	−40 to 125	−55 to 125	−25 to 85	°C
ESD (HBM)	2000	2000	1000	1000	1000	1000	1000	V
Offset Voltage (Max over temp)	± 5.5	± 5.5	± 9 ± 4	± 15 ± 4	± 15 ± 4	± 9 ± 4	± 9 ± 4	mV
Input Bias Current (typ / max)	3.5 / 25	3.5 / 25	25 / 250	25 / 250	25 / 250	25 / 100	25 / 250	nA
Response Time (typ)	1	1	1.3	1.3	1.3	1.3	1.3	µsec

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision U (November 2018) to Revision V (December 2022)	Page
• Updated the numbering format for tables, figures, and cross-references throughout the document.	1
• Added "B" version throughout. Added Device Family Table.	1

Changes from Revision T (June 2015) to Revision U (November 2018)	Page
• Changed LM239x temperature range from 125°C to 85°C in *Description* section	1
• Changed data sheet title	1
• Changed LM293AD to LM239AD in *Device Comparison Table*	4
• Added Input Current and related footnote in *Absolute Maximum Ratings*	6
• Changed layout of *Recommended Operating Conditions* temperatures to separate rows	7
• Changed values in the Thermal Information table to align with JEDEC standards	8
• Added LM2901V and LMV2901AV to LM2901 Elect Char Table title to make more clear which devices are covered	12
• Changed "Dual" to "Quad" and removed "Absolute Maximum" wording and mention of Q100 in *Overview* section text	22
• Changed and corrected text in *Feature Description* section	22
• Changed Example Values in *Typical Application Design Parameters* table	23
• Added *Receiving Notification of Documentation Updates* section	27

Changes from Revision S (August 2012) to Revision T (June 2015)	Page
• Deleted *Ordering Information* table.	1
• Added Military Disclaimer to *Features* list	1
• Added *Applications*, *Device Information* table, *Pin Configuration and Functions* section, *ESD Ratings* table, *Thermal Information* table, *Feature Description* section, *Device Functional Modes*, *Application and Implementation* section, *Power Supply Recommendations* section, *Layout* section, *Device and Documentation Support* section, and *Mechanical, Packaging, and Orderable Information* section. No specification changes	1

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5 Other Versions

OTHER QUALIFIED VERSIONS OF LM139-SP, LM239A, LM2901, LM2901AV, LM2901V:

- Automotive Q100: LM239A-Q1, LM2901B-Q1, LM2901-Q1, LM2901AV-Q1, LM2901V-Q1
- Enhanced Product: LM239A-EP
- Space: LM139-SP

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6 Pin Configuration and Functions

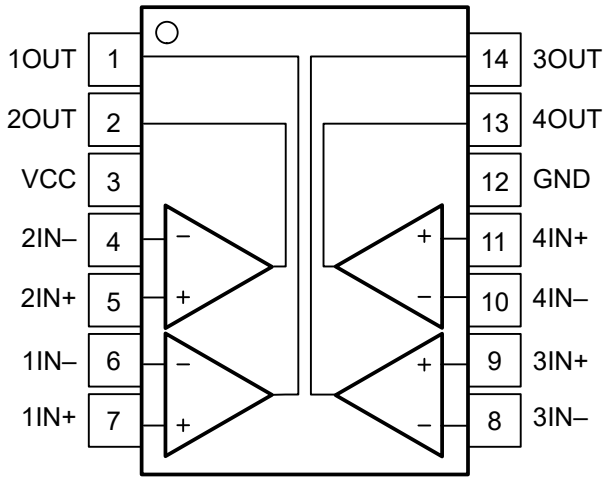
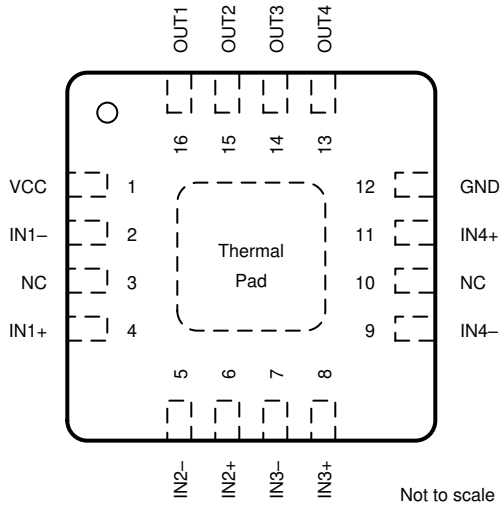


Figure 6-1. D, DB, N, NS, PW, DYY, J Packages
14-Pin SOIC, SSOP, PDIP, SO, TSSOP, SOT-23, CDIP
Top View



NOTE: Connect exposed thermal pad directly to GND pin.

Figure 6-2. RTE Package
16-Pad WQFN With Exposed Thermal Pad
Top View

Table 6-1. Pin Functions

PIN			I/O	DESCRIPTION
NAME[1]	D, DB, N, NS, PW, DYY, J	WQFN		
OUT1 [1]	1	16	Output	Output pin of the comparator 2
OUT2 [1]	2	15	Output	Output pin of the comparator 1
V_{CC}	3	1	—	Positive supply
IN2– [1]	4	5	Input	Negative input pin of the comparator 1
IN2+ [1]	5	6	Input	Positive input pin of the comparator 1
IN1– [1]	6	2	Input	Negative input pin of the comparator 2
IN1+ [1]	7	4	Input	Positive input pin of the comparator 2
IN3–	8	7	Input	Negative input pin of the comparator 3
IN3+	9	8	Input	Positive input pin of the comparator 3
IN4–	10	9	Input	Negative input pin of the comparator 4
IN4+	11	11	Input	Positive input pin of the comparator 4
GND	12	12	—	Negative supply
OUT4	13	13	Output	Output pin of the comparator 4
OUT3	14	14	Output	Output pin of the comparator 3
NC	—	3	—	No Internal Connection - Leave floating or GND
NC	—	10	—	No Internal Connection - Leave floating or GND
Thermal Pad	—	PAD	—	Connect directly to GND pin

(1) Some manufacturers transpose the names of channels 1 & 2. Electrically the pinouts are identical, just a difference in the channel naming convention.

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7 Specifications

7.1 Absolute Maximum Ratings for LM339B and LM2901B

over operating free-air temperature range (unless otherwise noted)(1)

	MIN	MAX	UNIT
Supply voltage: V_S = (V+) – (V–)	-0.3	38	V
Differential input voltage : V_{ID} (2)		±38	V
Input pins (IN+, IN–)	-0.3	38	V
Current into input pins (IN+, IN–)		-50	mA
Output pin (OUT)	-0.3	38	V
Output sink current		25	mA
Output short-circuit duration(3)		Unlimited	s
Junction temperature, T_J	TBD	150	°C
Storage temperature, T_{stg}	-65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) Differential voltages are at IN+ with respect to IN-
(3) Short circuits from outputs to V+ can cause excessive heating and eventual destruction.

7.2 Absolute Maximum Ratings for Non-B Versions

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V_{CC}	Supply voltage(2)			36	V
V_{ID}	Differential input voltage(3)			±36	V
V_I	Input voltage range (either input)		–0.3	36	V
I_K	Input current(5)			–50	mA
V_O	Output voltage			36	V
I_O	Output current			20	mA
	Duration of output short circuit to ground(4)		Unlimited		
T_J	Operating virtual-junction temperature			150	°C
	Case temperature for 60 s	FK package		260	°C
	Lead temperature 1.6 mm (1/16 in) from case for 60 s	J package		300	°C
T_{stg}	Storage temperature		–65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) All voltage values, except differential voltages, are with respect to network ground.
(3) Differential voltages are at xIN+ with respect to xIN–.
(4) Short circuits from outputs to V_{CC} can cause excessive heating and eventual destruction.
(5) Input current flows through parasitic diode to ground and will turn on parasitic transistors that will increase I_{CC} and may cause output to be incorrect. Normal operation resumes when input is removed.

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7.3 ESD Ratings for LM339B and LM2901B

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±2000	V
		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-002(2)	±1000	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process

7.4 ESD Ratings, Non-B Versions

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±500	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101(2)	±750	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.5 Recommended Operating Conditions for LM339B and LM2901B

over operating free-air temperature range (unless otherwise noted)

	MIN	MAX	UNIT
Supply voltage: $V_S = (V+) – (V–)$	2	36	V
Ambient temperature, T_A, LM339B	–40	85	°C
Ambient temperature, T_A, LM2901B	–40	125	°C
Input Voltage Range, V_{IVR}	(V–) – 0.1	(V+) – 2.0	V

7.6 Recommended Operating Conditions, Non-B Versions

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage	Non-V devices	2	30	V
		V devices	2	32	V
T_J	Junction temperature	LM139x	–55	125	°C
		LM239x	–25	85	
		LM339x	–0	70	
		LM2901x	–40	125	

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7.7 Thermal Information for LM339B and LM2901B

THERMAL METRIC(1)		LM339B, LM2901B					UNIT
		D (SOIC)	PW (TSSOP)	DDY (SOT-23)	RUC (QFN)	RTE (QFN)	
		14 PINS	14 PINS	14 PINS	14 PINS	16 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	111.2	136.6				°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	66.9	66.6				°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	67.8	79.8				°C/W
ψ_{JT}	Junction-to-top characterization parameter	28.0	17.8				°C/W
ψ_{JB}	Junction-to-board characterization parameter	67.4	79.3				°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	-	-	-			°C/W

(1) For more information about traditional and new thermal metrics, see the Semicondctor and IC Package Thermal Metrics report, SPRA953.

7.8 Thermal Information for Non-B Versions

THERMAL METRIC(1)		LMx39, LM2901x							UNIT
		D (SOIC)	DB (SSOP)	N (PDIP)	NS (SO)	PW (TSSOP)	J (CDIP)	W (CFP)	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	98.8	111.8	79	96.2	120	89.5	156.2	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	64.3	63.6	73.4	56.1	59	46.1	86.7	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	59.7	60.5	58.7	56.9	68.8	78.7	154.6	°C/W
ψ_{JT}	Junction-to-top characterization parameter	25.7	26.2	48.3	24.8	9.9	3	56.5	°C/W
ψ_{JB}	Junction-to-board characterization parameter	59.3	59.8	58.5	56.4	68.2	71.8	133.5	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	—	—	—	—	—	24.2	14.3	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

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7.9 Electrical Characteristics for LM339B

V_S = 5 V, V_{CM} = (V–) ; T_A = 25°C (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	V_S = 5 to 36V	–3.5	±0.37	3.5	mV
		V_S = 5 to 36V, T_A = –40°C to +85°C	–5.5		5.5	
I_B	Input bias current			–3	–25	nA
		T_A = –40°C to +85°C			–50	nA
I_{OS}	Input offset current		–25	±0.5	25	nA
		T_A = –40°C to +85°C	–50		50	nA
V_{CM}	Common mode range (1)	V_S = 3 to 36V	(V–)		(V+) – 1.5	V
		V_S = 3 to 36V, T_A = –40°C to +85°C	(V–)		(V+) – 2.0	V
A_{VD}	Large signal differential voltage amplification (2)	V_S = 15V, V_O = 1.4V to 11.4V; R_L ≥ 15k to (V+)	50	200		V/mV
V_{OL}	Low level output Voltage {swing from (V–)}	I_{SINK} ≤ 4mA, V_{ID} = -1V		110	400	mV
		I_{SINK} ≤ 4mA, V_{ID} = -1V T_A = –40°C to +85°C			550	mV
I_{OH-LKG}	High-level output leakage current	(V+) = V_O = 5 V; V_{ID} = 1V		0.1	50	nA
		(V+) = V_O = 36V; V_{ID} = 1V			100	nA
I_{OL}	Low level output current	V_{OL} = 1.5V; V_{ID} = -1V; V_S = 5V	6	21		mA
I_Q	Quiescent current (all comparators)	V_S = 5 V, no load		0.8	1.2	mA
		V_S = 36 V, no load, T_A = –40°C to +85°C		1	1.6	mA

(1) The voltage at either input should not be allowed to go negative by more than 0.3 V otherwise output may be incorrect and excessive input current can flow. The upper end of the common-mode voltage range is limited by V_{CC} – 2V. However only one input needs to be in the valid common mode range, the other input can go up the maximum V_{CC} level and the comparator provides a proper output state. Either or both inputs can go to maximum V_{CC} level without damage.
(2) This parameter is ensured by design and/or characterization and is not tested in production.

7.10 Electrical Characteristics for LM2901B

V_S = 5 V, V_{CM} = (V–) ; T_A = 25°C (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	V_S = 5 to 36V	–3.5	±0.37	3.5	mV
		V_S = 5 to 36V, T_A = –40°C to +125°C	–5.5		5.5	
I_B	Input bias current			–3	–25	nA
		T_A = –40°C to +125°C			–50	nA
I_{OS}	Input offset current		–25	±0.5	25	nA
		T_A = –40°C to +125°C	–50		50	nA
V_{CM}	Common mode range (1)	V_S = 3 to 36V	(V–)		(V+) – 1.5	V
		V_S = 3 to 36V, T_A = –40°C to +125°C	(V–)		(V+) – 2.0	V
A_{VD}	Large signal differential voltage amplification (2)	V_S = 15V, V_O = 1.4V to 11.4V; R_L ≥ 15k to (V+)	50	200		V/mV
V_{OL}	Low level output Voltage {swing from (V–)}	I_{SINK} ≤ 4mA, V_{ID} = -1V		110	400	mV
		I_{SINK} ≤ 4mA, V_{ID} = -1V T_A = –40°C to +125°C			550	mV
I_{OH-LKG}	High-level output leakage current	(V+) = V_O = 5 V; V_{ID} = 1V		0.1	50	nA
		(V+) = V_O = 36V; V_{ID} = 1V			100	nA
I_{OL}	Low level output current	V_{OL} = 1.5V; V_{ID} = -1V; V_S = 5V	6	21		mA
I_Q	Quiescent current (all comparators)	V_S = 5 V, no load		0.8	1.2	mA
		V_S = 36 V, no load, T_A = –40°C to +125°C		1	1.6	mA

(1) The voltage at either input should not be allowed to go negative by more than 0.3 V otherwise output may be incorrect and excessive input current can flow. The upper end of the common-mode voltage range is limited by V_{CC} – 2V. However only one input needs to be in the valid common mode range, the other input can go up the maximum V_{CC} level and the comparator provides a proper output state. Either or both inputs can go to maximum V_{CC} level without damage.
(2) This parameter is ensured by design and/or characterization and is not tested in production.

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7.11 Electrical Characteristics for LM139 and LM139A

at specified free-air temperature, V_{CC} = 5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS[1]		T_A [2]	LM139			LM139A			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{CC} = 5 V to 30 V, V_{IC} = V_{ICR} min, V_O = 1.4 V		25°C		2	5		1	2	mV
				Full range			9			4	
I_{IO}	Input offset current	V_O = 1.4 V		25°C		3	25		3	25	nA
				Full range			100			100	
I_{IB}	Input bias current	V_O = 1.4 V		25°C		–25	–100		–25	–100	nA
				Full range			–300			–300	
V_{ICR}	Common-mode input-voltage range[3]			25°C	0 to V_{CC} – 1.5			0 to V_{CC} – 1.5			V
				Full range	0 to V_{CC} – 2			0 to V_{CC} – 2			
A_{VD}	Large-signal differential-voltage amplification	V_{CC+} = ±7.5 V, V_O = –5 V to 5 V		25°C		200		50	200		V/mV
I_{OH}	High-level output current	V_{ID} = 1 V	V_{OH} = 5 V	25°C		0.1			0.1		nA
			V_{OH} = 30 V	Full range			1			1	µA
V_{OL}	Low-level output voltage	V_{ID} = –1 V,	I_{OL} = 4 mA	25°C		150	400		150	400	mV
				Full range			700			700	
I_{OL}	Low-level output current	V_{ID} = –1 V,	V_{OL} = 1.5 V	25°C	6	16		6	16		mA
I_{CC}	Supply current (four comparators)	V_O = 2.5 V,	No load	25°C		0.8	2		0.8	2	mA

(1) All characteristics are measured with zero common-mode input voltage, unless otherwise specified.
(2) Full range (MIN to MAX) for LM139 and LM139A is –55°C to +125°C. All characteristics are measured with zero common-mode input voltage, unless otherwise specified.
(3) The voltage at either input or common-mode must not be allowed to go negative by more than 0.3 V. The upper end of the common-mode voltage range is V_{CC+} – 1.5 V; however, one input can exceed V_{CC}, and the comparator will provide a proper output state as long as the other input remains in the common-mode range. Either or both inputs can go to 30 V without damage.

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7.12 Electrical Characteristics for LMx39 and LMx39A

at specified free-air temperature, V_{CC} = 5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS[1]		T_A [2]	LM239 LM339			LM239A LM339A			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{CC} = 5 V to 30 V, V_{IC} = V_{ICR} min, V_O = 1.4 V		25°C		2	5		1	3	mV
				Full range			9			4	
I_{IO}	Input offset current	V_O = 1.4 V		25°C		5	50		5	50	nA
				Full range			150			150	
I_{IB}	Input bias current	V_O = 1.4 V		25°C		–25	–250		–25	–250	nA
				Full range			–400			–400	
V_{ICR}	Common-mode input-voltage range[3]			25°C	0 to V_{CC} – 1.5			0 to V_{CC} – 1.5			V
				Full range	0 to V_{CC} – 2			0 to V_{CC} – 2			
A_{VD}	Large-signal differential-voltage amplification	V_{CC} = 15 V, V_O = 1.4 V to 11.4 V, R_L ≥ 15 kΩ to V_{CC}		25°C	50	200		50	200		V/mV
I_{OH}	High-level output current	V_{ID} = 1 V	V_{OH} = 5 V	25°C		0.1	50		0.1	50	nA
			V_{OH} = 30 V	Full range			1			1	µA
V_{OL}	Low-level output voltage	V_{ID} = –1 V,	I_{OL} = 4 mA	25°C		150	400		150	400	mV
				Full range			700			700	
I_{OL}	Low-level output current	V_{ID} = –1 V,	V_{OL} = 1.5 V	25°C	6	16		6	16		mA
I_{CC}	Supply current (four comparators)	V_O = 2.5 V,	No load	25°C		0.8	2		0.8	2	mA

(1) All characteristics are measured with zero common-mode input voltage, unless otherwise specified.
(2) Full range (MIN to MAX) for LM239/LM239A is –25°C to +85°C, and for LM339/LM339A is 0°C to 70°C. All characteristics are measured with zero common-mode input voltage, unless otherwise specified.
(3) The voltage at either input or common-mode must not be allowed to go negative by more than 0.3 V. The upper end of the common-mode voltage range is V_{CC+} – 1.5 V; however, one input can exceed V_{CC}, and the comparator will provide a proper output state as long as the other input remains in the common-mode range. Either or both inputs can go to 30 V without damage.

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7.13 Electrical Characteristics for LM2901, LM2901V and LM2901AV

at specified free-air temperature, V_{CC} = 5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS[1]		T_A [2]	LM2901			UNIT
					MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{IC} = V_{ICR} min, V_O = 1.4 V, V_{CC} = 5 V to MAX[3]	Non-A devices	25°C		2	7	mV
				Full range			15	
			A-suffix devices	25°C		1	2	
				Full range			4	
I_{IO}	Input offset current	V_O = 1.4 V		25°C		5	50	nA
				Full range			200	
I_{IB}	Input bias current	V_O = 1.4 V		25°C		–25	–250	nA
				Full range			–500	
V_{ICR}	Common-mode input-voltage range[4]			25°C	0 to V_{CC} – 1.5			V
				Full range	0 to V_{CC} – 2			
A_{VD}	Large-signal differential-voltage amplification	V_{CC} = 15 V, V_O = 1.4 V to 11.4 V, R_L ≥ 15 kΩ to V_{CC}		25°C	25	100		V/mV
I_{OH}	High-level output current	V_{ID} = 1 V	V_{OH} = 5 V	25°C		0.1	50	nA
			V_{OH} = V_{CC} MAX[3]	Full range			1	µA
V_{OL}	Low-level output voltage	V_{ID} = –1 V, I_{OL} = 4 mA	Non-V devices	25°C		150	500	mV
			V-suffix devices			150	400	
			All devices	Full range			700	
I_{OL}	Low-level output current	V_{ID} = –1 V,	V_{OL} = 1.5 V	25°C	6	16		mA
I_{CC}	Supply current (four comparators)	V_O = 2.5 V, No load	V_{CC} = 5 V	25°C		0.8	2	mA
			V_{CC} = MAX[3]			1	2.5	

(1) All characteristics are measured with zero common-mode input voltage, unless otherwise specified.
(2) Full range (MIN to MAX) for LM2901 is –40°C to +125°C. All characteristics are measured with zero common-mode input voltage, unless otherwise specified.
(3) V_{CC} MAX = 30 V for non-V devices, and 32 V for V-suffix devices
(4) The voltage at either input or common-mode must not be allowed to go negative by more than 0.3 V. The upper end of the common-mode voltage range is V_{CC+} – 1.5 V; however, one input can exceed V_{CC}, and the comparator will provide a proper output state as long as the other input remains in the common-mode range. Either or both inputs can go to V_{CC} MAX without damage.

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7.14 Switching Characteristics for LM139 and LM139A

V_{CC} = 5 V, T_A = 25°C

PARAMETER	TEST CONDITIONS		LM139 LM139A	UNIT
			TYP	
Response time	R_L connected to 5 V through 5.1 kΩ, C_L = 15 pF(1) (2)	100-mV input step with 5-mV overdrive	1.3	µs
		TTL-level input step	0.3	

(1) C_L includes probe and jig capacitance.
(2) The response time specified is the interval between the input step function and the instant when the output crosses 1.4 V.

7.15 Switching Characteristics for LM339B and LM2901B

V_S = 5V, $V_{O\ PULLUP}$ = 5V, V_{CM} = V_S/2, C_L = 15pF, R_L = 5.1k Ohm, T_A = 25°C (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_{response}$	Propagation delay time, high-to-low; Small scale input signal (1)	Input overdrive = 5mV, Input step = 100mV		1000		ns
$t_{response}$	Propagation delay time, high-to-low; TTL input signal (1)	TTL input with V_{ref} = 1.4V		300		ns

(1) High-to-low and low-to-high refers to the transition at the input.

7.16 Switching Characteristics for LMx39 and LMx39A

V_{CC} = 5 V, T_A = 25°C

PARAMETER	TEST CONDITIONS		LM239 LM239A LM339 LM339A	UNIT
			TYP	
Response time	R_L connected to 5 V through 5.1 kΩ, C_L = 15 pF(1) (2)	100-mV input step with 5-mV overdrive	1.3	µs
		TTL-level input step	0.3	

(1) C_L includes probe and jig capacitance.
(2) The response time specified is the interval between the input step function and the instant when the output crosses 1.4 V.

7.17 Switching Characteristics for LM2901

V_{CC} = 5 V, T_A = 25°C

PARAMETER	TEST CONDITIONS		LM2901	UNIT
			TYP	
Response time	R_L connected to 5 V through 5.1 kΩ, C_L = 15 pF(1) (2)	100-mV input step with 5-mV overdrive	1.3	µs
		TTL-level input step	0.3	

(1) C_L includes probe and jig capacitance.
(2) The response time specified is the interval between the input step function and the instant when the output crosses 1.4 V.

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7.18 Typical Characteristics for LM339B and LM2901B Only

T_A = 25°C, V_S = 5 V, R_{PULLUP} = 5.1k, C_L = 15 pF, V_{CM} = 0 V, $V_{UNDERDRIVE}$ = 100 mV, $V_{OVERDRIVE}$ = 100 mV unless otherwise noted.

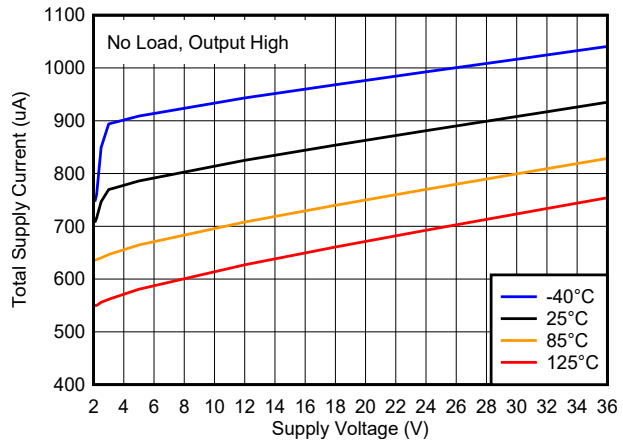


Figure 7-1. Total Supply Current vs. Supply Voltage

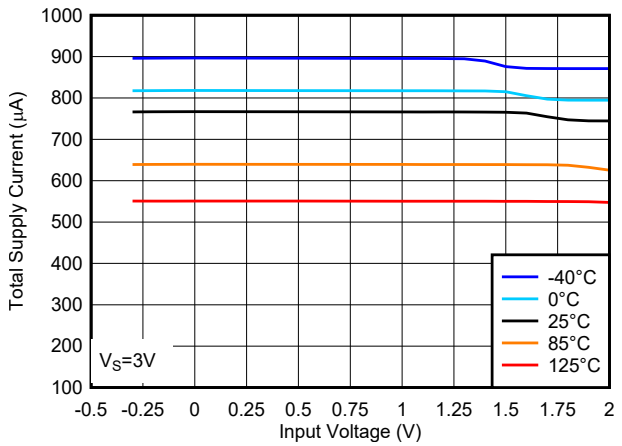


Figure 7-2. Total Supply Current vs. Input Voltage at 3V

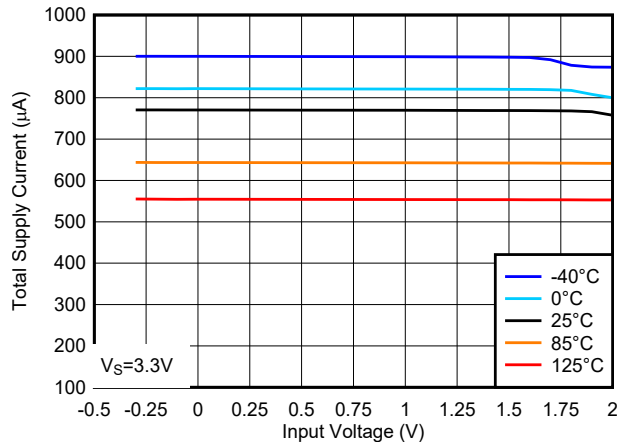


Figure 7-3. Total Supply Current vs. Input Voltage at 3.3V

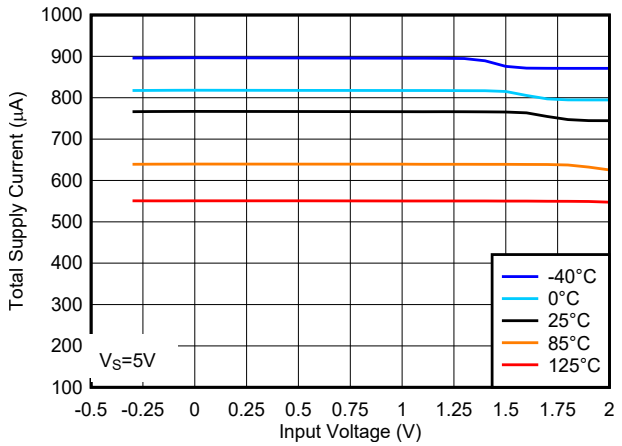


Figure 7-4. Total Supply Current vs. Input Voltage at 5V

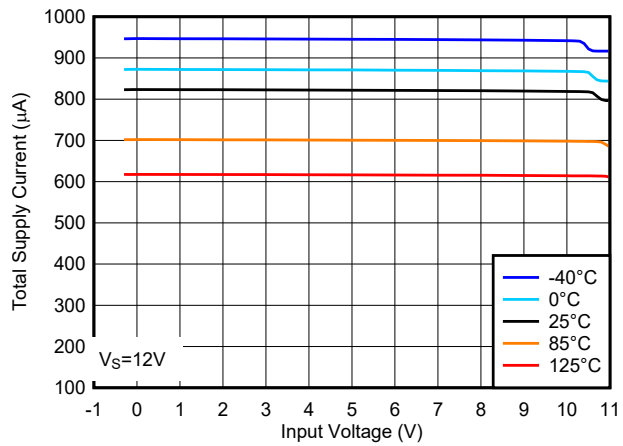


Figure 7-5. Total Supply Current vs. Input Voltage at 12V

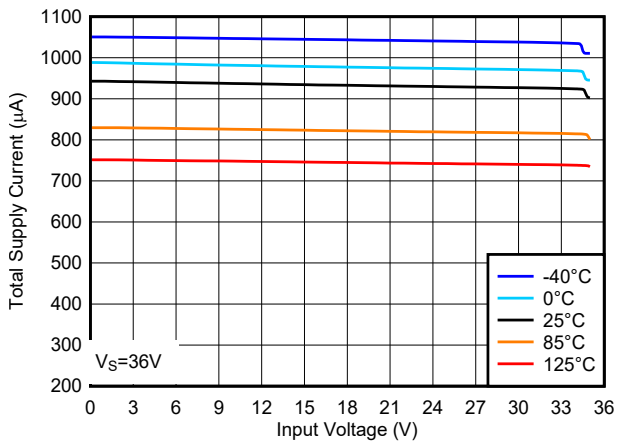


Figure 7-6. Total Supply Current vs. Input Voltage at 36V

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7.18 Typical Characteristics for LM339B and LM2901B Only (continued)

T_A = 25°C, V_S = 5 V, R_{PULLUP} = 5.1k, C_L = 15 pF, V_{CM} = 0 V, $V_{UNDERDRIVE}$ = 100 mV, $V_{OVERDRIVE}$ = 100 mV unless otherwise noted.

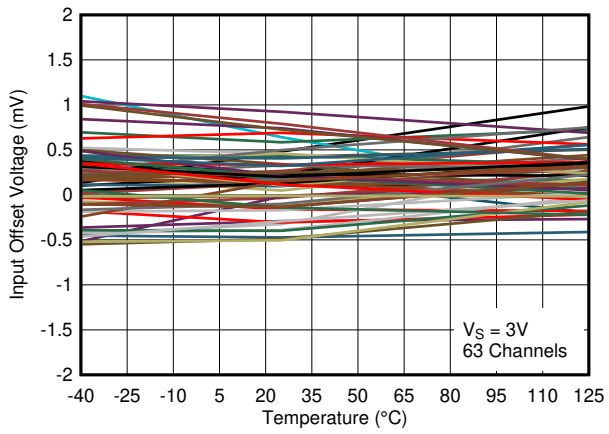


Figure 7-7. Input Offset Voltage vs. Temperature at 3V

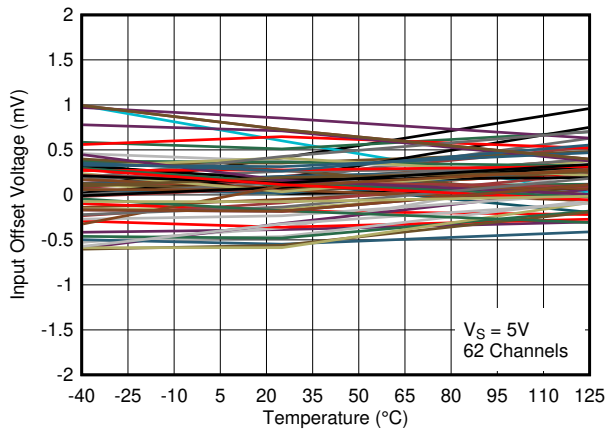


Figure 7-8. Input Offset Voltage vs. Temperature at 5V

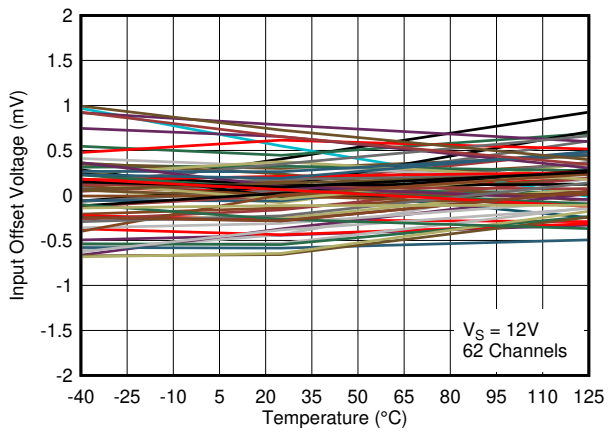


Figure 7-9. Input Offset Voltage vs. Temperature at 12V

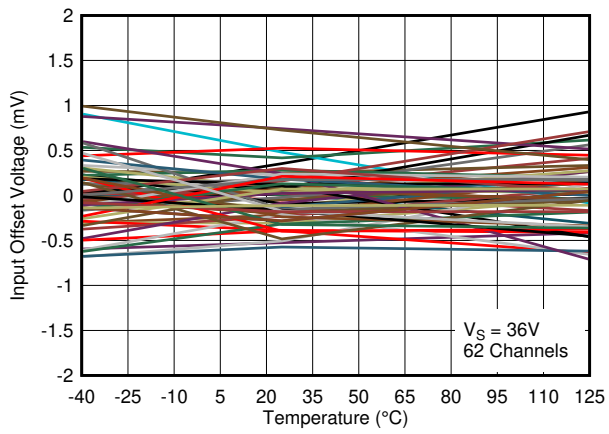


Figure 7-10. Input Offset Voltage vs. Temperature at 36

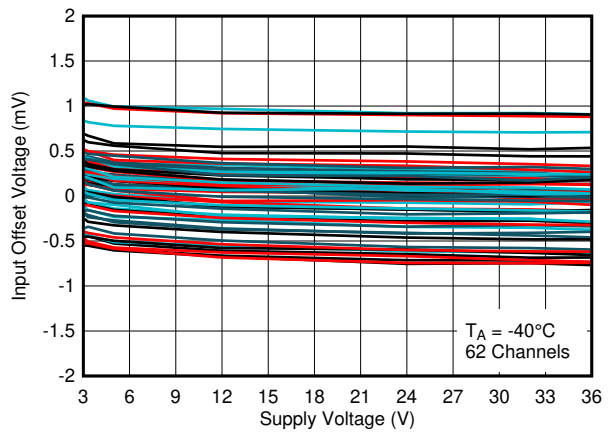


Figure 7-11. Input Offset Voltage vs. Supply Voltage at -40°C

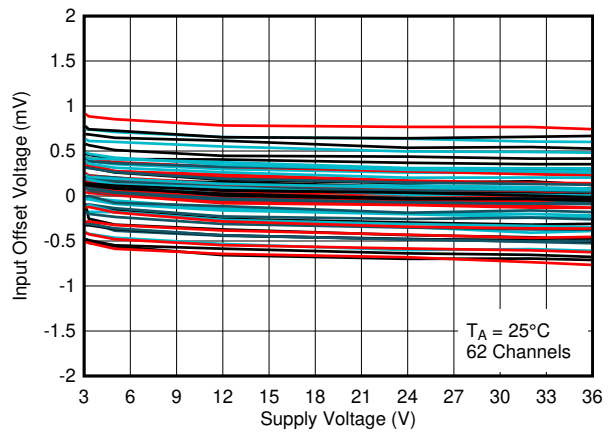


Figure 7-12. Input Offset Voltage vs. Supply Voltage at 25°C

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7.18 Typical Characteristics for LM339B and LM2901B Only (continued)

T_A = 25°C, V_S = 5 V, R_{PULLUP} = 5.1k, C_L = 15 pF, V_{CM} = 0 V, $V_{UNDERDRIVE}$ = 100 mV, $V_{OVERDRIVE}$ = 100 mV unless otherwise noted.

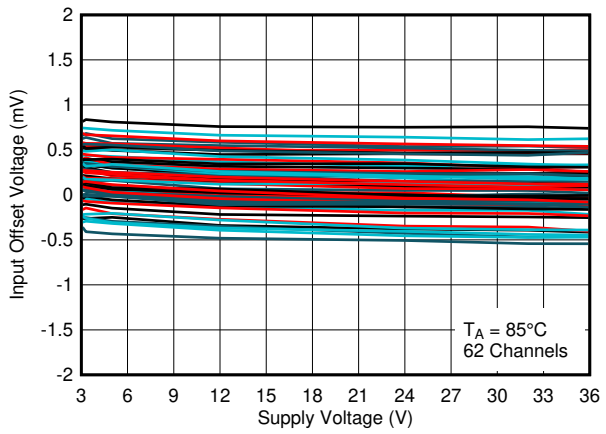


Figure 7-13. Input Offset Voltage vs. Supply Voltage at 85°C

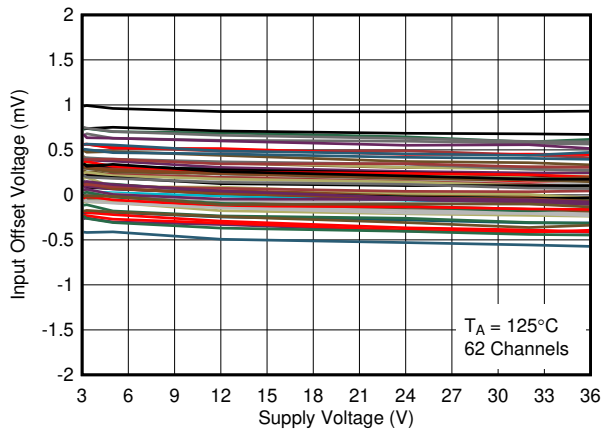


Figure 7-14. Input Offset Voltage vs. Supply Voltage at 125°C

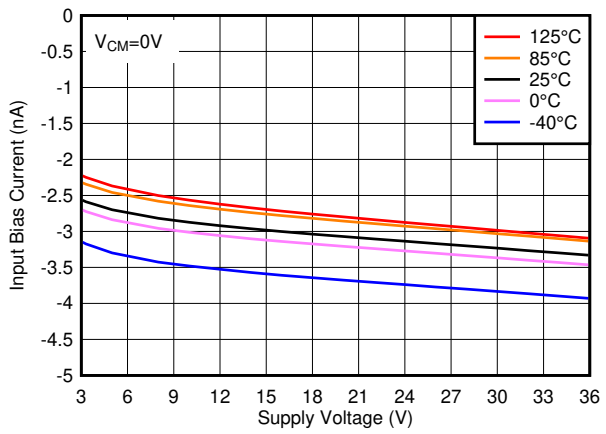


Figure 7-15. Input Bias Current vs. Supply Voltage

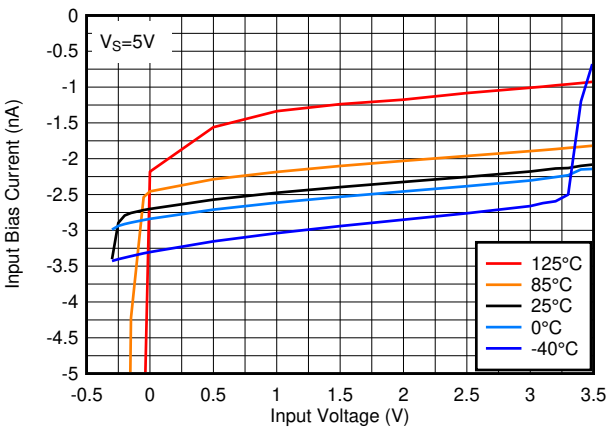


Figure 7-16. Input Bias Current vs. Input Voltage at 5V

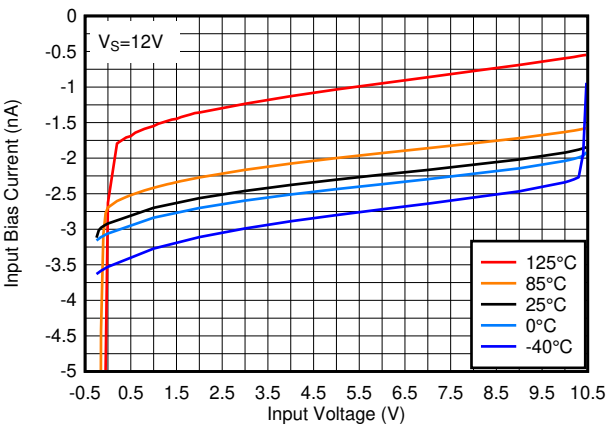


Figure 7-17. Input Bias Current vs. Input Voltage at 12V

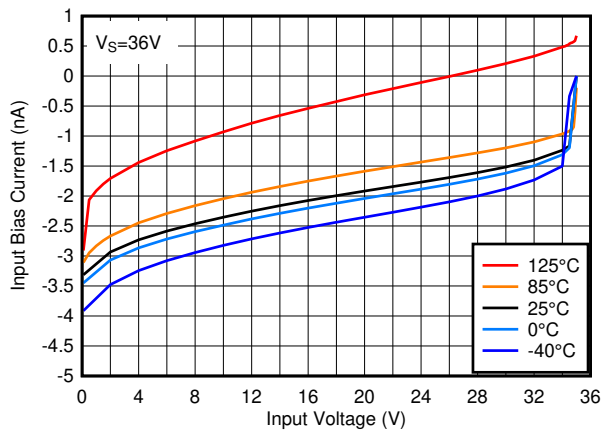


Figure 7-18. Input Bias Current vs. Input Voltage at 36V

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7.18 Typical Characteristics for LM339B and LM2901B Only (continued)

T_A = 25°C, V_S = 5 V, R_{PULLUP} = 5.1k, C_L = 15 pF, V_{CM} = 0 V, $V_{UNDERDRIVE}$ = 100 mV, $V_{OVERDRIVE}$ = 100 mV unless otherwise noted.

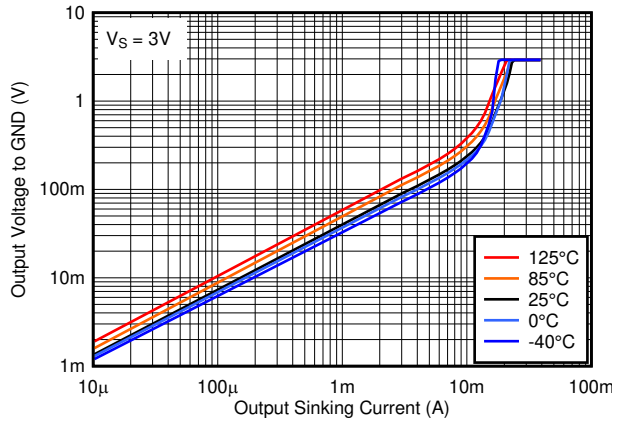


Figure 7-19. Output Low Voltage vs. Output Sinking Current at 3V

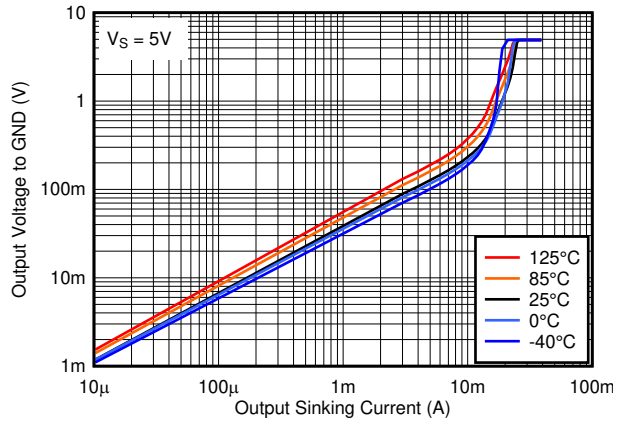


Figure 7-20. Output Low Voltage vs. Output Sinking Current at 5V

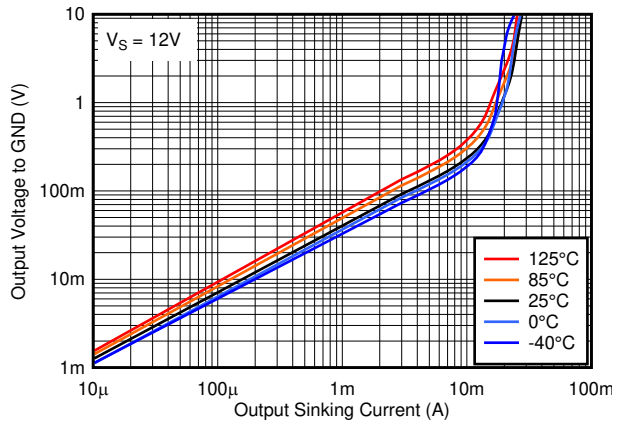


Figure 7-21. Output Low Voltage vs. Output Sinking Current at 12V

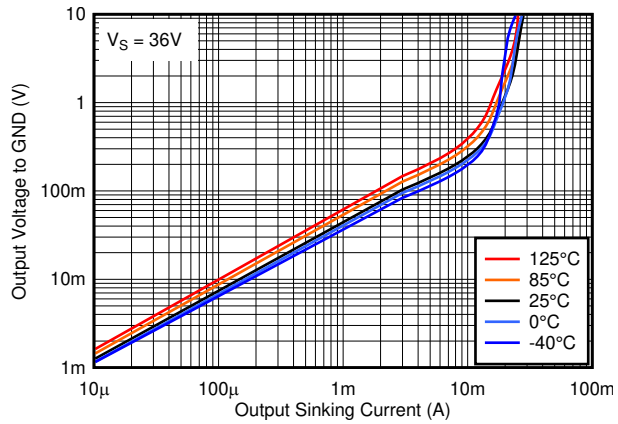


Figure 7-22. Output Low Voltage vs.Output Sinking Current at 36V

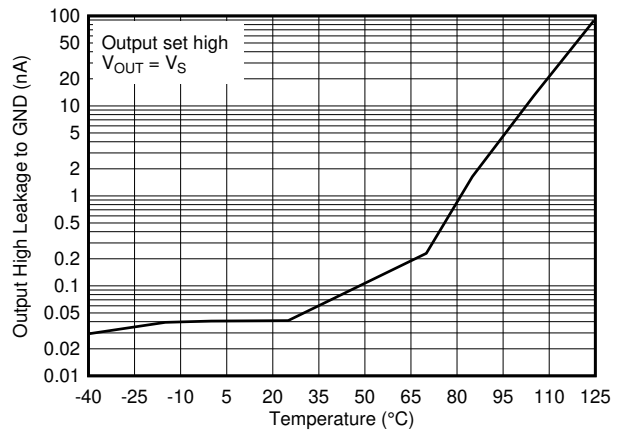


Figure 7-23. Output High Leakage Current vs.Temperature at 5V

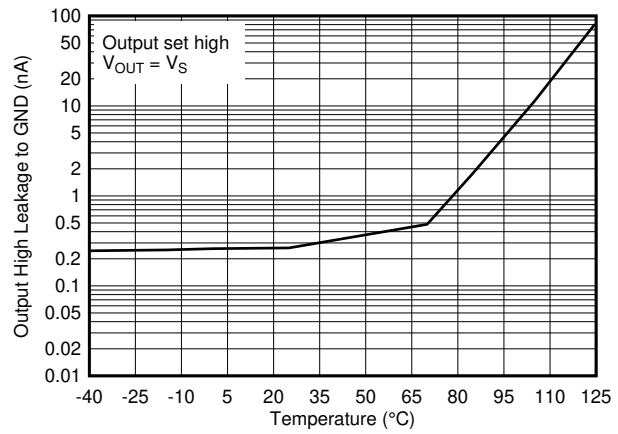


Figure 7-24. Output High Leakage Current vs. Temperature at 36V

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7.18 Typical Characteristics for LM339B and LM2901B Only (continued)

T_A = 25°C, V_S = 5 V, R_{PULLUP} = 5.1k, C_L = 15 pF, V_{CM} = 0 V, $V_{UNDERDRIVE}$ = 100 mV, $V_{OVERDRIVE}$ = 100 mV unless otherwise noted.

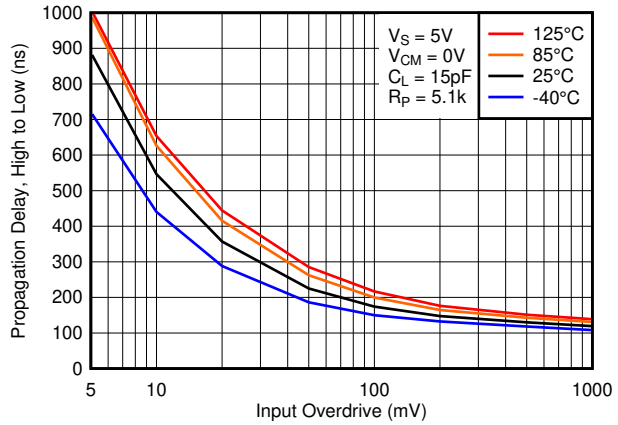


Figure 7-25. High to Low Propagation Delay vs. Input Overdrive Voltage, 5V

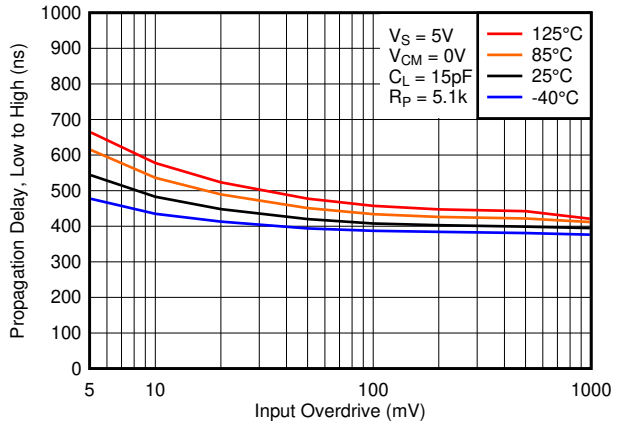


Figure 7-26. Low to High Propagation Delay vs. Input Overdrive Voltage, 5V

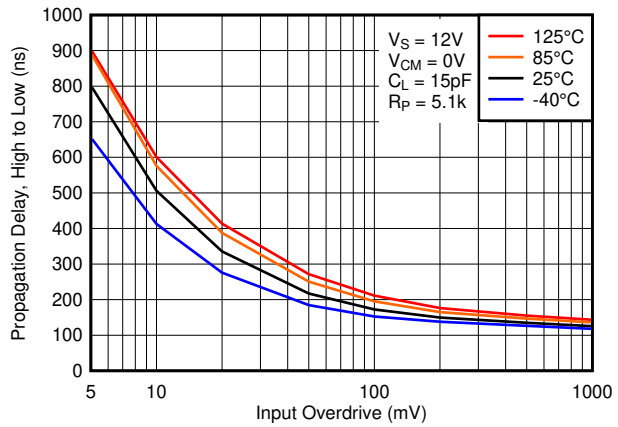


Figure 7-27. High to Low Propagation Delay vs. Input Overdrive Voltage, 12V

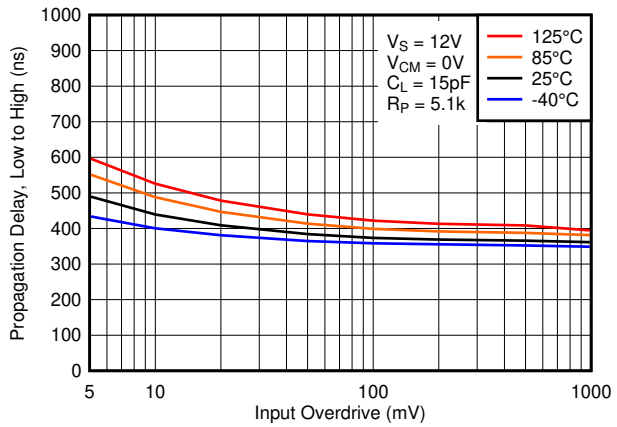


Figure 7-28. Low to High Propagation Delay vs. Input Overdrive Voltage, 12V

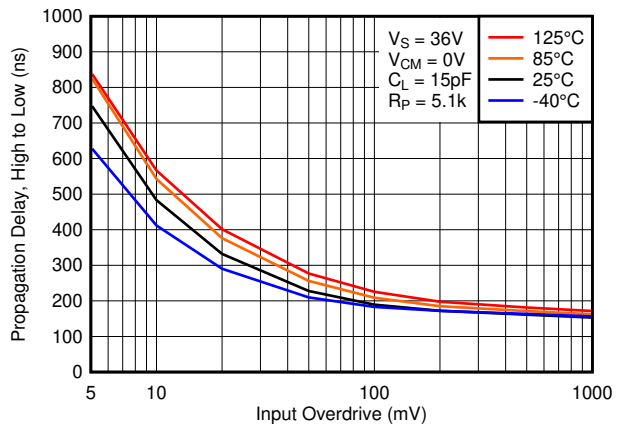


Figure 7-29. High to Low Propagation Delay vs. Input Overdrive Voltage, 36V

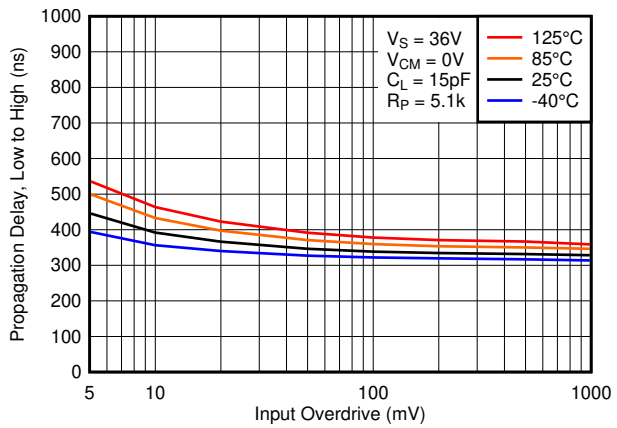


Figure 7-30. Low to High Propagation Delay vs. Input Overdrive Voltage, 36V

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7.18 Typical Characteristics for LM339B and LM2901B Only (continued)

T_A = 25°C, V_S = 5 V, R_{PULLUP} = 5.1k, C_L = 15 pF, V_{CM} = 0 V, $V_{UNDERDRIVE}$ = 100 mV, $V_{OVERDRIVE}$ = 100 mV unless otherwise noted.

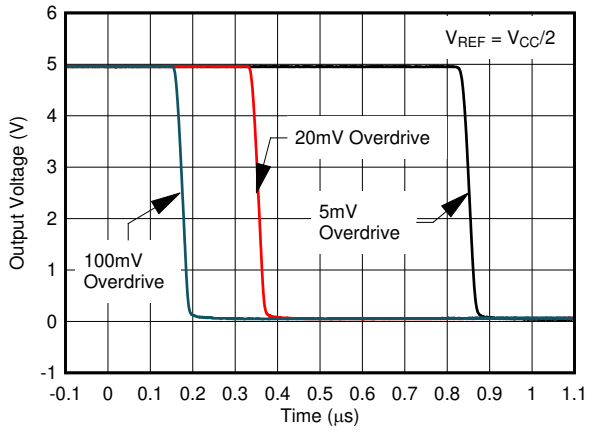


Figure 7-31. Response Time for Various Overdrives, High-to-Low Transition

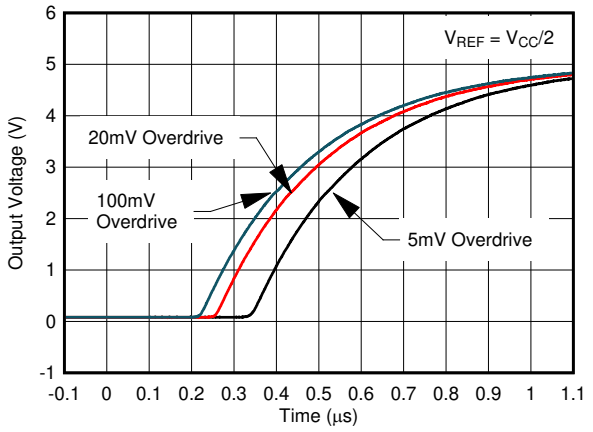


Figure 7-32. Response Time for Various Overdrives, Low-to-High Transition

7.19 Typical Characteristics, Non-B Versions

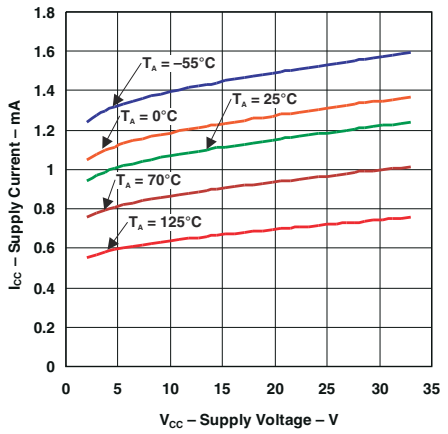


Figure 7-33. Supply Current vs Supply Voltage

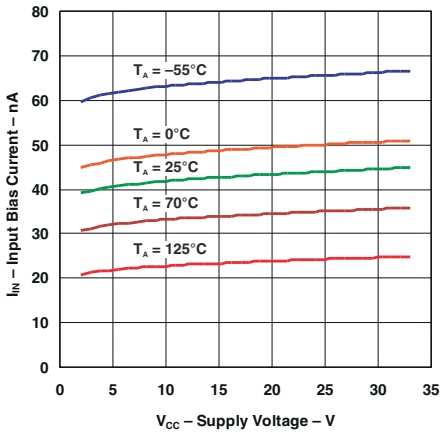


Figure 7-34. Input Bias Current vs Supply Voltage

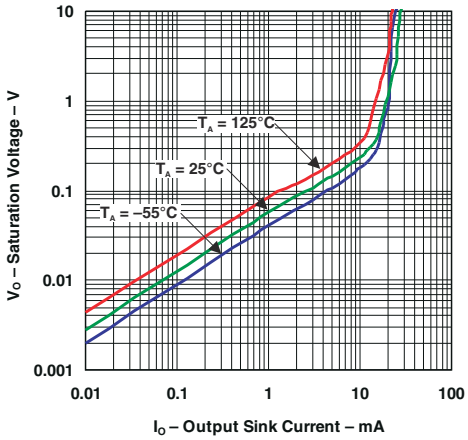


Figure 7-35. Output Saturation Voltage

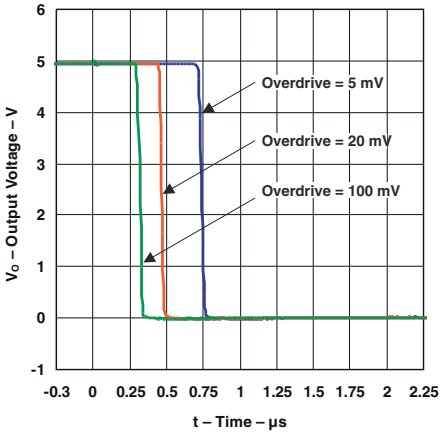


Figure 7-36. Response Time for Various Overdrives Negative Transition

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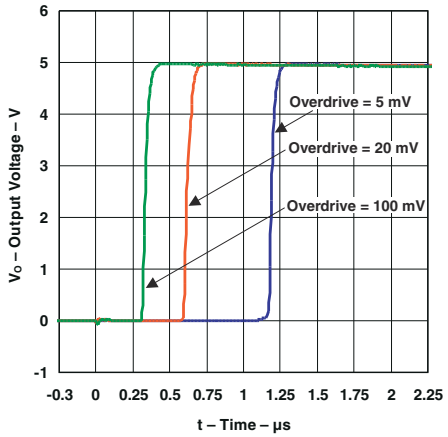


Figure 7-37. Response Time for Various Overdrives Positive Transition

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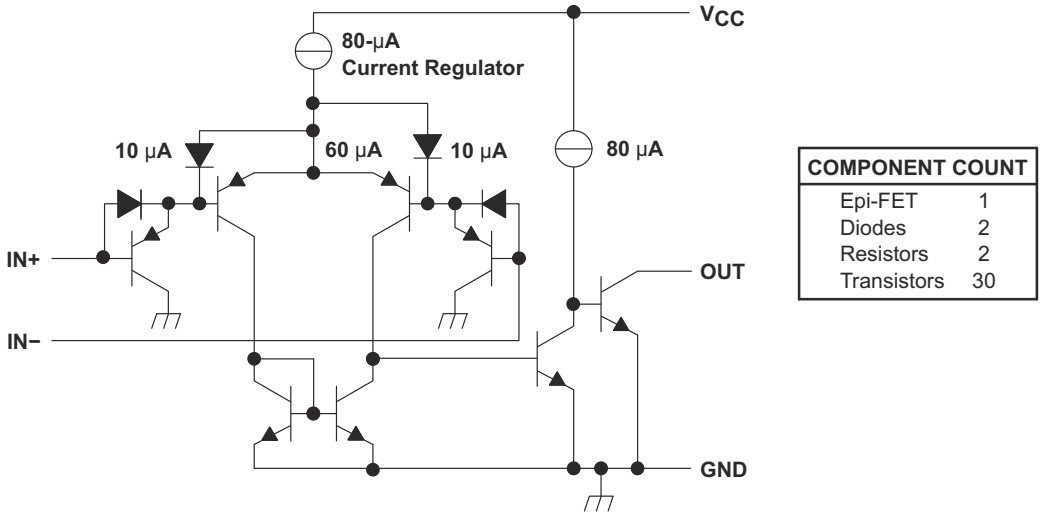
8 Detailed Description

8.1 Overview

The LMx39 and LM2901x are quad comparators with the ability to operate up to an absolute maximum of 36 V on the supply pin. This standard device has proven ubiquity and versatility across a wide range of applications. This is due to very wide supply voltages range (2 V up to 32 V), low Iq, and fast response of the device.

The open-drain output allows the user to configure the output logic low voltage (V_{OL}) and allows the comparator to be used in AND functionality.

8.2 Functional Block Diagram



COMPONENT COUNT	
Epi-FET	1
Diodes	2
Resistors	2
Transistors	30

Figure 8-1. Schematic (Each Comparator)

8.3 Feature Description

The comparator consists of a PNP Darlington pair input, allowing the device to operate with very high gain and fast response with minimal input bias current. The input Darlington pair creates a limit on the input common-mode voltage capability, allowing the comparator to accurately function from ground to (V_{CC} – 1.5 V) differential input. Allow for (V_{CC} – 2 V) at cold temperature.

The output consists of an open-collector NPN (pulldown or low-side) transistor. The output NPN sinks current when the negative input voltage is higher than the positive input voltage and the offset voltage. The VOL is resistive and scales with the output current. See the *Section 7* section for V_{OL} values with respect to the output current.

8.4 Device Functional Modes

8.4.1 Voltage Comparison

The comparator operates solely as a voltage comparator, comparing the differential voltage between the positive and negative pins and outputting a logic low or high impedance (logic high with pullup) based on the input differential polarity.

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9 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

Typically, a comparator compares either a single signal to a reference, or to two differnt signals. Many users take advantage of the open-drain output to drive the comparison logic output to a logic voltage level to an MCU or logic device. The wide supply range and high voltage capability makes LMx39 or LM2901x optimal for level shifting to a higher or lower voltage.

9.2 Typical Application

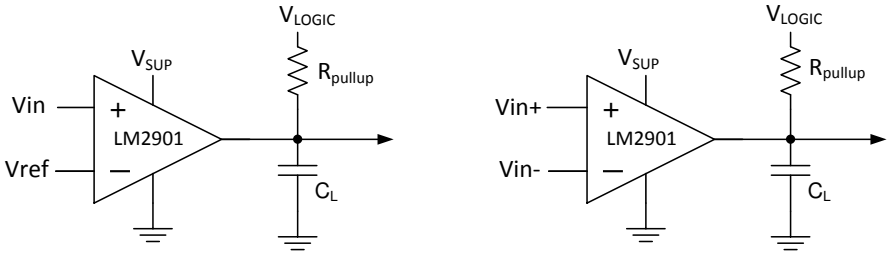


Figure 9-1. Single-ended and Differential Comparator Configurations

9.2.1 Design Requirements

For this design example, use the parameters listed in Table 9-1 as the input parameters.

Table 9-1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input Voltage Range	0 V to Vsup-1.5 V
Supply Voltage	4.5 V to V_{CC} maximum
Logic Supply Voltage	0 V to V_{CC} maximum
Output Current (R_{PULLUP})	1 µA to 4 mA
Input Overdrive Voltage	100 mV
Reference Voltage	2.5 V
Load Capacitance (C_L)	15 pF

9.2.2 Detailed Design Procedure

When using the LMx39 in a general comparator application, determine the following:

- Input voltage range
- Minimum overdrive voltage
- Output and drive current
- Response time

9.2.2.1 Input Voltage Range

When choosing the input voltage range, the input common-mode voltage range (V_{ICR}) must be taken in to account. If temperature operation is above or below 25°C the V_{ICR} can range from 0 V to V_{CC}– 2 V. This limits the input voltage range to as high as V_{CC}– 2 V and as low as 0 V. Operation outside of this range can yield incorrect comparisons.

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The following list describes the outcomes of some input voltage situations.

- When both IN– and IN+ are both within the common-mode range:
  - If IN– is higher than IN+ and the offset voltage, the output is low and the output transistor is sinking current
  - If IN– is lower than IN+ and the offset voltage, the output is high impedance and the output transistor is not conducting
- When IN– is higher than common mode and IN+ is within common mode, the output is low and the output transistor is sinking current
- When IN+ is higher than common mode and IN– is within common mode, the output is high impedance and the output transistor is not conducting
- When IN– and IN+ are both higher than common mode, the output is low and the output transistor is sinking current

9.2.2.2 Minimum Overdrive Voltage

Overdrive voltage is the differential voltage produced between the positive and negative inputs of the comparator over the offset voltage (V_{IO}). To make an accurate comparison, the overdrive voltage (V_{OD}) must be higher than the input offset voltage (V_{IO}). Overdrive voltage can also determine the response time of the comparator, with the response time decreasing with increasing overdrive. Figure 9-2 and Figure 9-3 show positive and negative response times with respect to overdrive voltage.

9.2.2.3 Output and Drive Current

Output current is determined by the load and pullup resistance and logic and pullup voltage. The output current produces a low-level output voltage (V_{OL}) from the comparator, where V_{OL} is proportional to the output current.

The output current can also effect the transient response.

9.2.2.4 Response Time

Response time is a function of input over-drive. See the *Section 7.19* graphs for typical response times. The rise and fall times can be determined by the load capacitance (C_L), load/pull-up resistance (R_{PULLUP}) and equivalent collector-emitter resistance (R_{CE}).

- The rise time (τ_R) is approximately $\tau_R \sim R_{PULLUP} \times C_L$
- The fall time (τ_F) is approximately $\tau_F \sim R_{CE} \times C_L$
  - R_{CE} can be determined by taking the slope of Figure 7-35 in its linear region at the desired temperature, or by dividing the V_{OL} by I_{OUT}

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9.2.3 Application Curves

Figure 9-2 and Figure 9-3 were generated with scope probe parasitic capacitance of 50 pF.

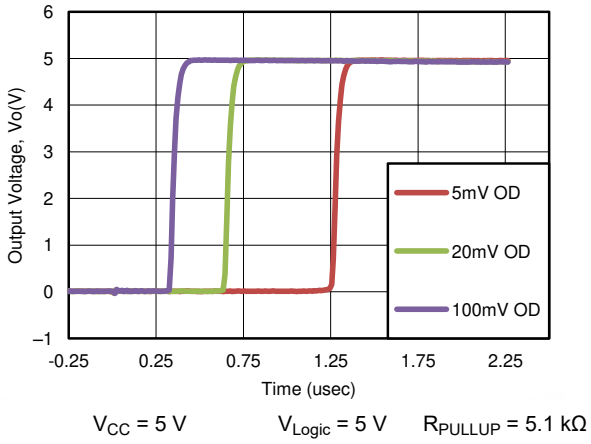


Figure 9-2. Response Time vs Output Voltage (Positive Transition)

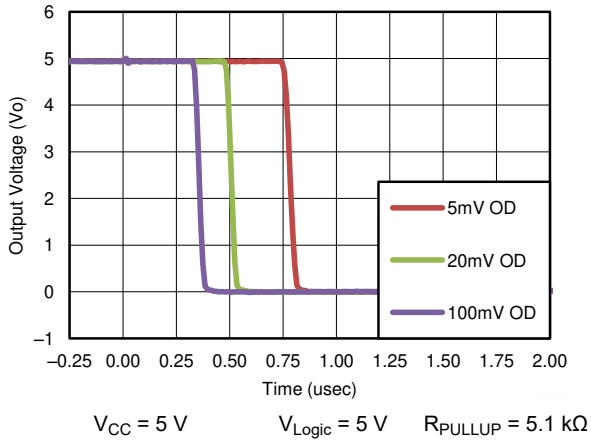


Figure 9-3. Response Time vs Output Voltage (Negative Transition)

10 Power Supply Recommendations

For fast response and comparison applications with noisy or AC inputs, use a bypass capacitor on the supply pin to reject any variation on the supply voltage. This variation can affect the common-mode range of the comparator input and create an inaccurate comparison.

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11 Layout

11.1 Layout Guidelines

To create an accurate comparator application without hysteresis, maintain a stable power supply with minimized noise and glitches, which can affect the high level input common-mode voltage range. To achieve this accuracy, add a bypass capacitor between the supply voltage and ground. Place a bypass capacitor on the positive power supply and negative supply (if available).

Note

If a negative supply is not being used, do not place a capacitor between the GND pin of the device and system ground.

11.2 Layout Example

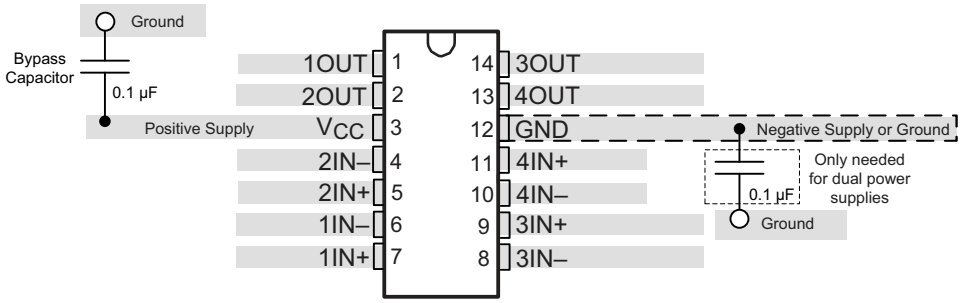


Figure 11-1. LMx39 Layout Example

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12 Device and Documentation Support

12.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 12-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
LM139	Click here	Click here	Click here	Click here	Click here
LM239	Click here	Click here	Click here	Click here	Click here
LM339	Click here	Click here	Click here	Click here	Click here
LM139A	Click here	Click here	Click here	Click here	Click here
LM239A	Click here	Click here	Click here	Click here	Click here
LM339A	Click here	Click here	Click here	Click here	Click here
LM2901	Click here	Click here	Click here	Click here	Click here
LM2901AV	Click here	Click here	Click here	Click here	Click here
LM2901V	Click here	Click here	Click here	Click here	Click here

12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.3 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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12.4 Trademarks

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12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.6 Glossary

TI Glossary — This glossary lists and explains terms, acronyms, and definitions.

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13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser based versions of this data sheet, refer to the left hand navigation.

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LM139AD	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	LM139A	Samples
LM139ADG4	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	LM139A	Samples
LM139ADR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	LM139A	Samples
LM139ADRG4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	LM139A	Samples
LM139D	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	LM139	Samples
LM139DG4	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	LM139	Samples
LM139DR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	LM139	Samples
LM139DRG4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	LM139	Samples
LM239AD	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-25 to 85	LM239A	Samples
LM239ADE4	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-25 to 85	LM239A	Samples
LM239ADR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU | SN	Level-1-260C-UNLIM	-25 to 85	LM239A	Samples
LM239ADRE4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-25 to 85	LM239A	Samples
LM239ADRG4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-25 to 85	LM239A	Samples
LM239D	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-25 to 85	LM239	Samples
LM239DE4	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-25 to 85	LM239	Samples
LM239DG4	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-25 to 85	LM239	Samples
LM239DR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU | SN	Level-1-260C-UNLIM	-25 to 85	LM239	Samples
LM239DRG3	ACTIVE	SOIC	D	14	2500	RoHS & Green	SN	Level-1-260C-UNLIM	-25 to 85	LM239	Samples
LM239DRG4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-25 to 85	LM239	Samples
LM239N	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU | SN	N / A for Pkg Type	-25 to 85	LM239N	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LM239NE4	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-25 to 85	LM239N	Samples
LM239PW	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-25 to 85	L239	Samples
LM239PWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU | SN	Level-1-260C-UNLIM	-25 to 85	L239	Samples
LM239PWRG4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-25 to 85	L239	Samples
LM2901AVQDR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2901AV	Samples
LM2901AVQDRG4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2901AV	Samples
LM2901AVQPWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2901AV	Samples
LM2901AVQPWRG4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2901AV	Samples
LM2901BIPWR	ACTIVE	TSSOP	PW	14	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LM2901B	Samples
LM2901D	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LM2901	Samples
LM2901DE4	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LM2901	Samples
LM2901DG4	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LM2901	Samples
LM2901DR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU | SN	Level-1-260C-UNLIM	-40 to 125	LM2901	Samples
LM2901DRE4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LM2901	Samples
LM2901DRG3	ACTIVE	SOIC	D	14	2500	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	LM2901	Samples
LM2901DRG4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LM2901	Samples
LM2901N	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 125	LM2901N	Samples
LM2901NE4	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 125	LM2901N	Samples
LM2901NSR	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LM2901	Samples
LM2901PW	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2901	Samples
LM2901PWG4	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2901	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LM2901PWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU | SN	Level-1-260C-UNLIM	-40 to 125	L2901	Samples
LM2901PWRG3	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	L2901	Samples
LM2901PWRG4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2901	Samples
LM2901VQDR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2901V	Samples
LM2901VQPWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2901V	Samples
LM2901VQPWRG4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2901V	Samples
LM339AD	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	LM339A	Samples
LM339ADBR	ACTIVE	SSOP	DB	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	L339A	Samples
LM339ADE4	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	LM339A	Samples
LM339ADG4	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	LM339A	Samples
LM339ADR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU | SN	Level-1-260C-UNLIM	0 to 70	LM339A	Samples
LM339ADRE4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	LM339A	Samples
LM339ADRG4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	LM339A	Samples
LM339AN	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU | SN	N / A for Pkg Type	0 to 70	LM339AN	Samples
LM339ANE4	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	LM339AN	Samples
LM339ANSR	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	LM339A	Samples
LM339ANSRG4	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	LM339A	Samples
LM339APW	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	L339A	Samples
LM339APWG4	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	L339A	Samples
LM339APWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU | SN	Level-1-260C-UNLIM	0 to 70	L339A	Samples
LM339APWRG4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	L339A	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LM339BIPWR	ACTIVE	TSSOP	PW	14	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LM339B	Samples
LM339D	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	LM339	Samples
LM339DBR	ACTIVE	SSOP	DB	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	LM339	Samples
LM339DE4	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	LM339	Samples
LM339DG4	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	LM339	Samples
LM339DR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU | SN	Level-1-260C-UNLIM	0 to 70	LM339	Samples
LM339DRE4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	LM339	Samples
LM339DRG3	ACTIVE	SOIC	D	14	2500	RoHS & Green	SN	Level-1-260C-UNLIM	0 to 70	LM339	Samples
LM339DRG4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	LM339	Samples
LM339N	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU | SN	N / A for Pkg Type	0 to 70	LM339N	Samples
LM339NE3	ACTIVE	PDIP	N	14	25	RoHS & Non-Green	SN	N / A for Pkg Type	0 to 70	LM339N	Samples
LM339NE4	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	LM339N	Samples
LM339NSR	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	LM339	Samples
LM339NSRG4	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	LM339	Samples
LM339PW	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	L339	Samples
LM339PWG4	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	L339	Samples
LM339PWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU | SN	Level-1-260C-UNLIM	0 to 70	L339	Samples
LM339PWRE4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	L339	Samples
LM339PWRG3	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	SN	Level-1-260C-UNLIM	0 to 70	L339	Samples
LM339PWRG4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	L339	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF LM139, LM239A, LM2901, LM2901AV, LM2901V :

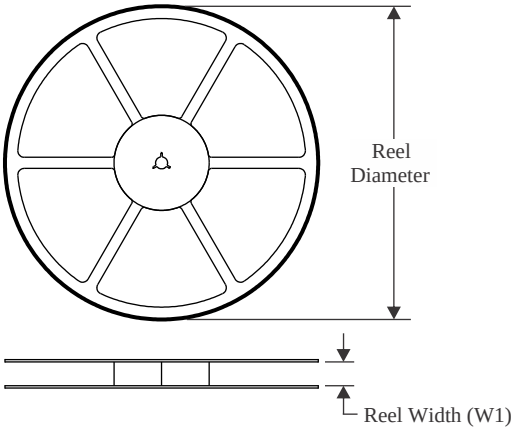
- Automotive : LM239A-Q1, LM2901-Q1, LM2901AV-Q1, LM2901V-Q1
- Enhanced Product : LM239A-EP
- Space : LM139-SP

NOTE: Qualified Version Definitions:

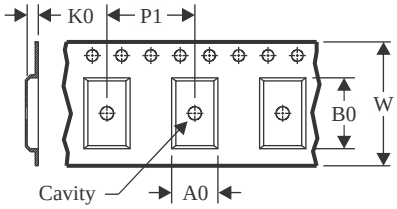
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product - Supports Defense, Aerospace and Medical Applications
- Space - Radiation tolerant, ceramic packaging and qualified for use in Space-based application

TAPE AND REEL INFORMATION

REEL DIMENSIONS

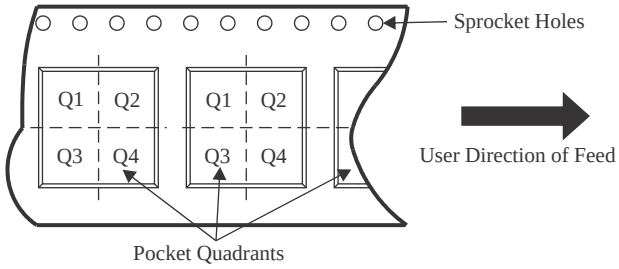


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

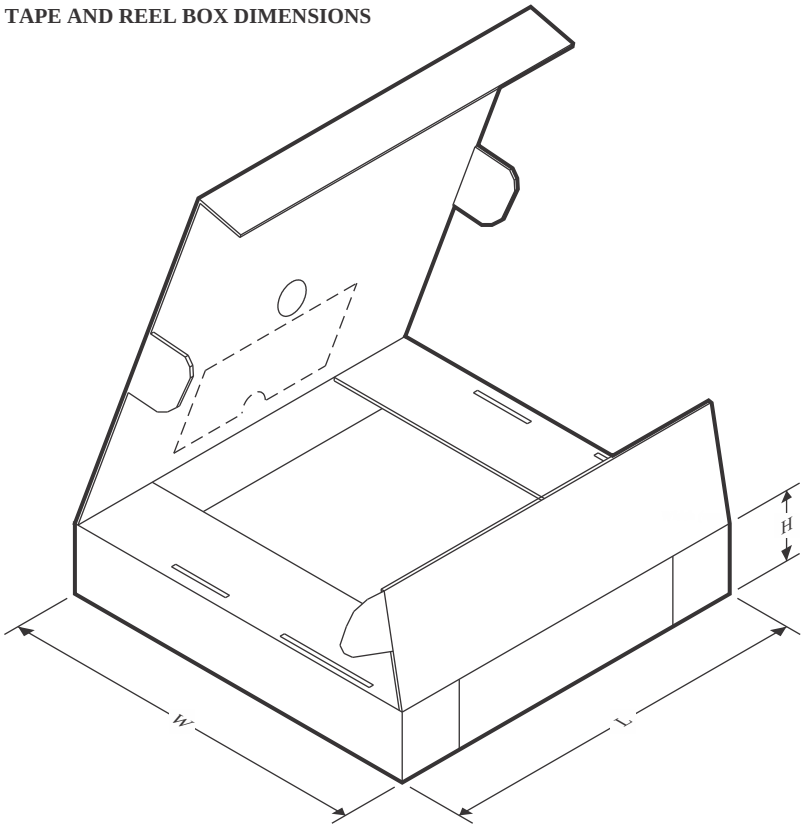


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM139ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LM139ADRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LM139DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LM139DRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LM239ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LM239ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LM239DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LM239DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LM239DR	SOIC	D	14	2500	330.0	16.8	6.5	9.5	2.1	8.0	16.0	Q1
LM239DRG3	SOIC	D	14	2500	330.0	17.5	6.4	9.05	2.1	8.0	16.0	Q1
LM239DRG3	SOIC	D	14	2500	330.0	16.8	6.5	9.5	2.1	8.0	16.0	Q1
LM239DRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LM239DRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LM239PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LM239PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LM239PWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM2901AVQPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LM2901AVQPWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LM2901DR	SOIC	D	14	2500	330.0	16.8	6.5	9.5	2.1	8.0	16.0	Q1
LM2901DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LM2901DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LM2901DRG3	SOIC	D	14	2500	330.0	16.8	6.5	9.5	2.1	8.0	16.0	Q1
LM2901DRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LM2901DRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LM2901NSR	SO	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
LM2901PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LM2901PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LM2901PWRG3	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LM2901PWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LM2901VQPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LM2901VQPWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LM339ADBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
LM339ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LM339ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LM339ADR	SOIC	D	14	2500	330.0	16.8	6.5	9.5	2.1	8.0	16.0	Q1
LM339ADRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LM339ADRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LM339ANSR	SO	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
LM339APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LM339APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LM339APWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LM339DBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
LM339DR	SOIC	D	14	2500	330.0	16.8	6.5	9.5	2.1	8.0	16.0	Q1
LM339DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LM339DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LM339DRG3	SOIC	D	14	2500	330.0	16.8	6.5	9.5	2.1	8.0	16.0	Q1
LM339DRG3	SOIC	D	14	2500	330.0	17.5	6.4	9.05	2.1	8.0	16.0	Q1
LM339DRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LM339DRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LM339NSR	SO	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
LM339PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LM339PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LM339PWRG3	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LM339PWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS

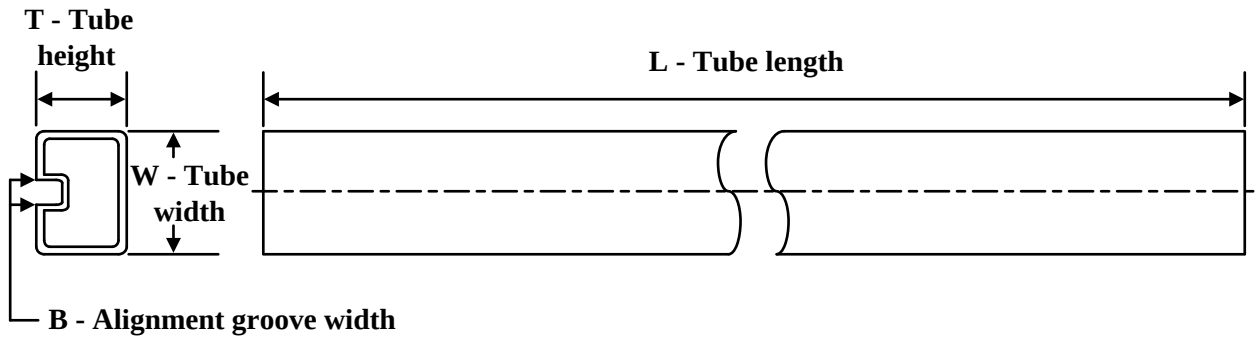


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM139ADR	SOIC	D	14	2500	350.0	350.0	43.0
LM139ADRG4	SOIC	D	14	2500	350.0	350.0	43.0
LM139DR	SOIC	D	14	2500	350.0	350.0	43.0
LM139DRG4	SOIC	D	14	2500	350.0	350.0	43.0
LM239ADR	SOIC	D	14	2500	356.0	356.0	35.0
LM239ADR	SOIC	D	14	2500	340.5	336.1	32.0
LM239DR	SOIC	D	14	2500	356.0	356.0	35.0
LM239DR	SOIC	D	14	2500	340.5	336.1	32.0
LM239DR	SOIC	D	14	2500	364.0	364.0	27.0
LM239DRG3	SOIC	D	14	2500	333.2	345.9	28.6
LM239DRG3	SOIC	D	14	2500	364.0	364.0	27.0
LM239DRG4	SOIC	D	14	2500	356.0	356.0	35.0
LM239DRG4	SOIC	D	14	2500	340.5	336.1	32.0
LM239PWR	TSSOP	PW	14	2000	356.0	356.0	35.0
LM239PWR	TSSOP	PW	14	2000	364.0	364.0	27.0
LM239PWRG4	TSSOP	PW	14	2000	356.0	356.0	35.0
LM2901AVQPWR	TSSOP	PW	14	2000	356.0	356.0	35.0
LM2901AVQPWRG4	TSSOP	PW	14	2000	356.0	356.0	35.0

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM2901DR	SOIC	D	14	2500	364.0	364.0	27.0
LM2901DR	SOIC	D	14	2500	340.5	336.1	32.0
LM2901DR	SOIC	D	14	2500	356.0	356.0	35.0
LM2901DRG3	SOIC	D	14	2500	364.0	364.0	27.0
LM2901DRG4	SOIC	D	14	2500	340.5	336.1	32.0
LM2901DRG4	SOIC	D	14	2500	356.0	356.0	35.0
LM2901NSR	SO	NS	14	2000	356.0	356.0	35.0
LM2901PWR	TSSOP	PW	14	2000	364.0	364.0	27.0
LM2901PWR	TSSOP	PW	14	2000	356.0	356.0	35.0
LM2901PWRG3	TSSOP	PW	14	2000	364.0	364.0	27.0
LM2901PWRG4	TSSOP	PW	14	2000	356.0	356.0	35.0
LM2901VQPWR	TSSOP	PW	14	2000	356.0	356.0	35.0
LM2901VQPWRG4	TSSOP	PW	14	2000	356.0	356.0	35.0
LM339ADBR	SSOP	DB	14	2000	356.0	356.0	35.0
LM339ADR	SOIC	D	14	2500	356.0	356.0	35.0
LM339ADR	SOIC	D	14	2500	340.5	336.1	32.0
LM339ADR	SOIC	D	14	2500	364.0	364.0	27.0
LM339ADRG4	SOIC	D	14	2500	356.0	356.0	35.0
LM339ADRG4	SOIC	D	14	2500	340.5	336.1	32.0
LM339ANSR	SO	NS	14	2000	356.0	356.0	35.0
LM339APWR	TSSOP	PW	14	2000	356.0	356.0	35.0
LM339APWR	TSSOP	PW	14	2000	364.0	364.0	27.0
LM339APWRG4	TSSOP	PW	14	2000	356.0	356.0	35.0
LM339DBR	SSOP	DB	14	2000	356.0	356.0	35.0
LM339DR	SOIC	D	14	2500	364.0	364.0	27.0
LM339DR	SOIC	D	14	2500	356.0	356.0	35.0
LM339DR	SOIC	D	14	2500	340.5	336.1	32.0
LM339DRG3	SOIC	D	14	2500	364.0	364.0	27.0
LM339DRG3	SOIC	D	14	2500	333.2	345.9	28.6
LM339DRG4	SOIC	D	14	2500	340.5	336.1	32.0
LM339DRG4	SOIC	D	14	2500	356.0	356.0	35.0
LM339NSR	SO	NS	14	2000	356.0	356.0	35.0
LM339PWR	TSSOP	PW	14	2000	356.0	356.0	35.0
LM339PWR	TSSOP	PW	14	2000	364.0	364.0	27.0
LM339PWRG3	TSSOP	PW	14	2000	364.0	364.0	27.0
LM339PWRG4	TSSOP	PW	14	2000	356.0	356.0	35.0

TUBE



*All dimensions are nominal

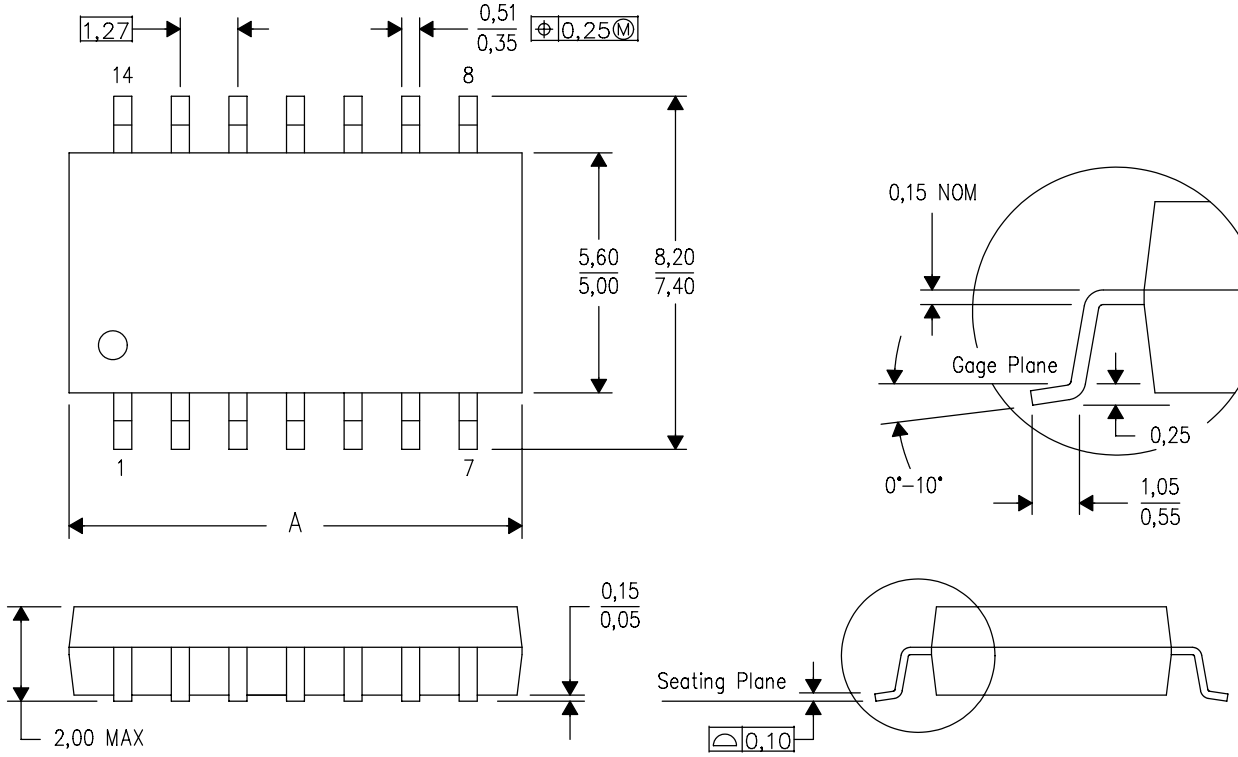
Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
LM139AD	D	SOIC	14	50	505.46	6.76	3810	4
LM139ADG4	D	SOIC	14	50	505.46	6.76	3810	4
LM139D	D	SOIC	14	50	505.46	6.76	3810	4
LM139DG4	D	SOIC	14	50	505.46	6.76	3810	4
LM239AD	D	SOIC	14	50	506.6	8	3940	4.32
LM239AD	D	SOIC	14	50	507	8	3940	4.32
LM239ADE4	D	SOIC	14	50	506.6	8	3940	4.32
LM239ADE4	D	SOIC	14	50	507	8	3940	4.32
LM239D	D	SOIC	14	50	506.6	8	3940	4.32
LM239D	D	SOIC	14	50	507	8	3940	4.32
LM239DE4	D	SOIC	14	50	507	8	3940	4.32
LM239DE4	D	SOIC	14	50	506.6	8	3940	4.32
LM239DG4	D	SOIC	14	50	507	8	3940	4.32
LM239DG4	D	SOIC	14	50	506.6	8	3940	4.32
LM239N	N	PDIP	14	25	506.1	9	600	5.4
LM239N	N	PDIP	14	25	506	13.97	11230	4.32
LM239NE4	N	PDIP	14	25	506	13.97	11230	4.32
LM239NE4	N	PDIP	14	25	506.1	9	600	5.4
LM239PW	PW	TSSOP	14	90	530	10.2	3600	3.5
LM2901D	D	SOIC	14	50	506.6	8	3940	4.32
LM2901DE4	D	SOIC	14	50	506.6	8	3940	4.32
LM2901DG4	D	SOIC	14	50	506.6	8	3940	4.32
LM2901N	N	PDIP	14	25	506	13.97	11230	4.32
LM2901NE4	N	PDIP	14	25	506	13.97	11230	4.32
LM2901PW	PW	TSSOP	14	90	530	10.2	3600	3.5
LM2901PWG4	PW	TSSOP	14	90	530	10.2	3600	3.5
LM339AD	D	SOIC	14	50	506.6	8	3940	4.32
LM339AD	D	SOIC	14	50	507	8	3940	4.32
LM339ADE4	D	SOIC	14	50	507	8	3940	4.32

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
LM339ADE4	D	SOIC	14	50	506.6	8	3940	4.32
LM339ADG4	D	SOIC	14	50	506.6	8	3940	4.32
LM339ADG4	D	SOIC	14	50	507	8	3940	4.32
LM339AN	N	PDIP	14	25	506	13.97	11230	4.32
LM339AN	N	PDIP	14	25	506	13.97	11230	4.32
LM339AN	N	PDIP	14	25	506.1	9	600	5.4
LM339ANE4	N	PDIP	14	25	506.1	9	600	5.4
LM339ANE4	N	PDIP	14	25	506	13.97	11230	4.32
LM339ANE4	N	PDIP	14	25	506	13.97	11230	4.32
LM339APW	PW	TSSOP	14	90	530	10.2	3600	3.5
LM339APWG4	PW	TSSOP	14	90	530	10.2	3600	3.5
LM339D	D	SOIC	14	50	506.6	8	3940	4.32
LM339D	D	SOIC	14	50	507	8	3940	4.32
LM339DE4	D	SOIC	14	50	506.6	8	3940	4.32
LM339DE4	D	SOIC	14	50	507	8	3940	4.32
LM339DG4	D	SOIC	14	50	507	8	3940	4.32
LM339DG4	D	SOIC	14	50	506.6	8	3940	4.32
LM339N	N	PDIP	14	25	506.1	9	600	5.4
LM339N	N	PDIP	14	25	506	13.97	11230	4.32
LM339N	N	PDIP	14	25	506	13.97	11230	4.32
LM339NE3	N	PDIP	14	25	506.1	9	600	5.4
LM339NE4	N	PDIP	14	25	506	13.97	11230	4.32
LM339NE4	N	PDIP	14	25	506	13.97	11230	4.32
LM339PW	PW	TSSOP	14	90	530	10.2	3600	3.5
LM339PWG4	PW	TSSOP	14	90	530	10.2	3600	3.5

MECHANICAL DATA

NS (R-PDSO-G)** **PLASTIC SMALL-OUTLINE PACKAGE**

14-PINS SHOWN

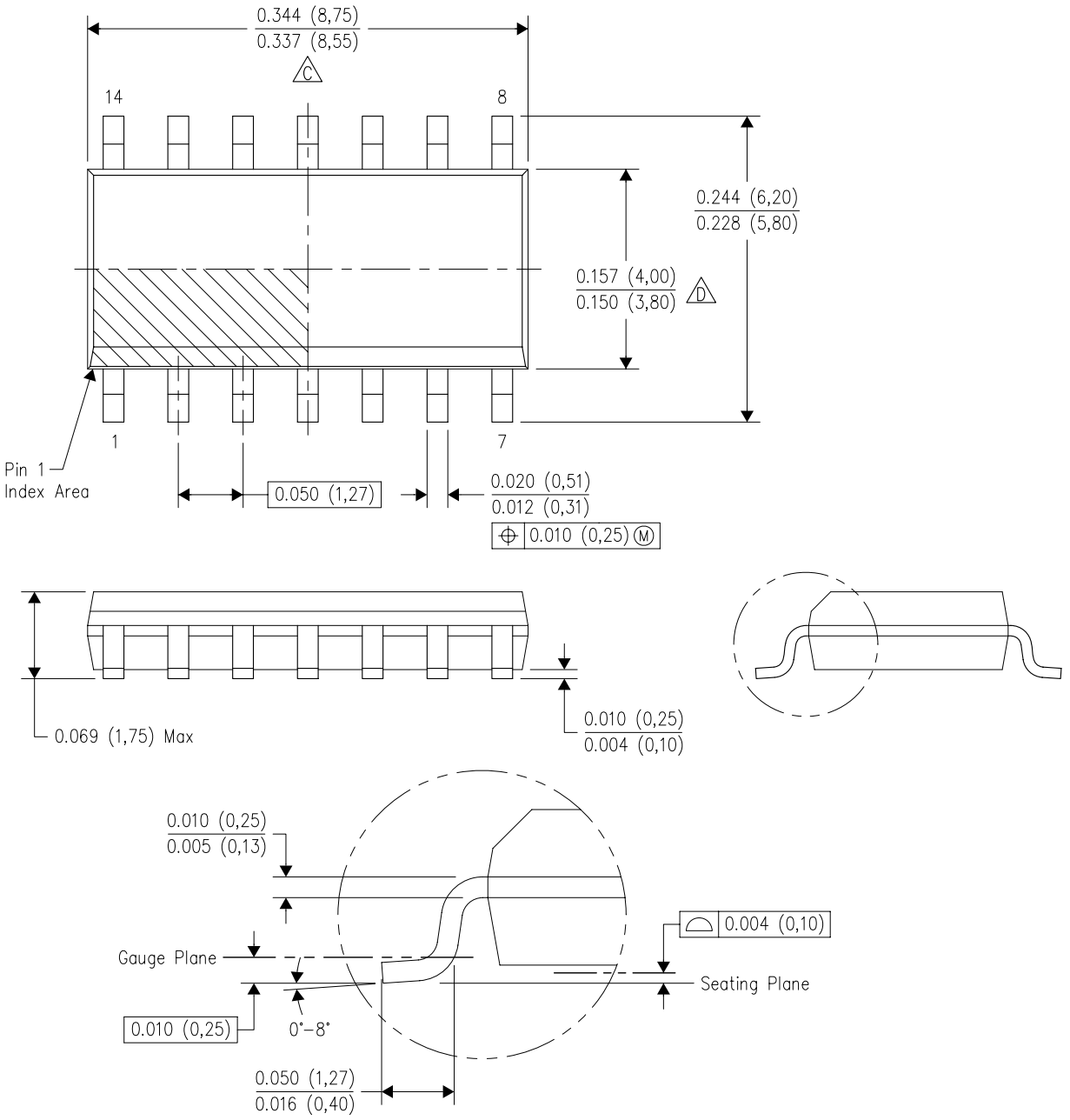


DIM \ PINS **	14	16	20	24
A MAX	10,50	10,50	12,90	15,30
A MIN	9,90	9,90	12,30	14,70

4040062/C 03/03

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

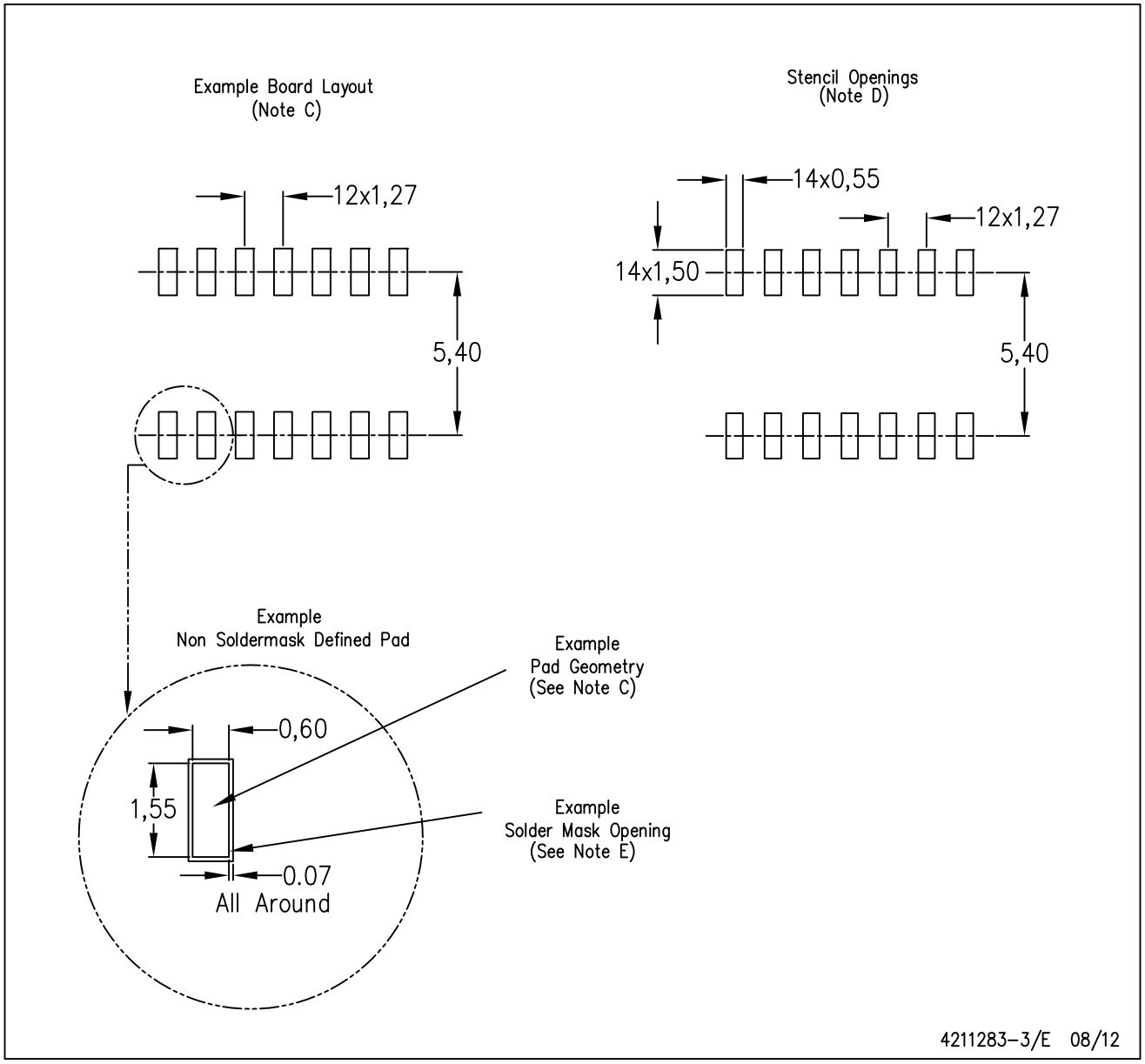
D (R–PDSO–G14) PLASTIC SMALL OUTLINE



4040047–5/M 06/11

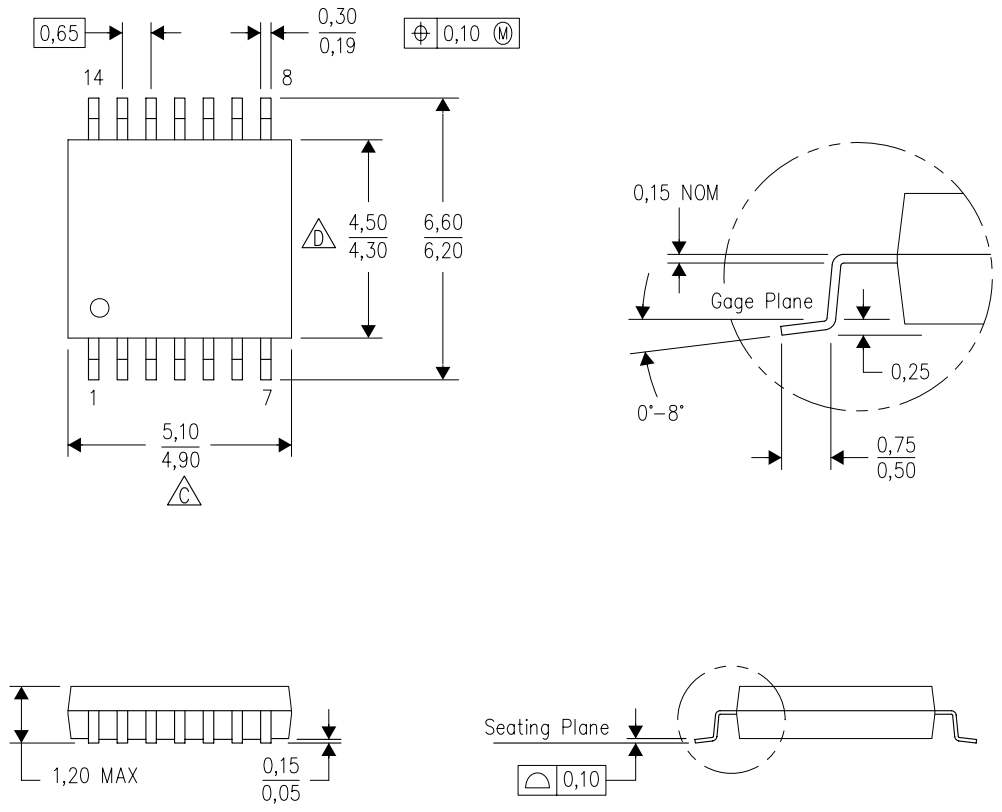
NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AB.

D (R–PDSO–G14) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

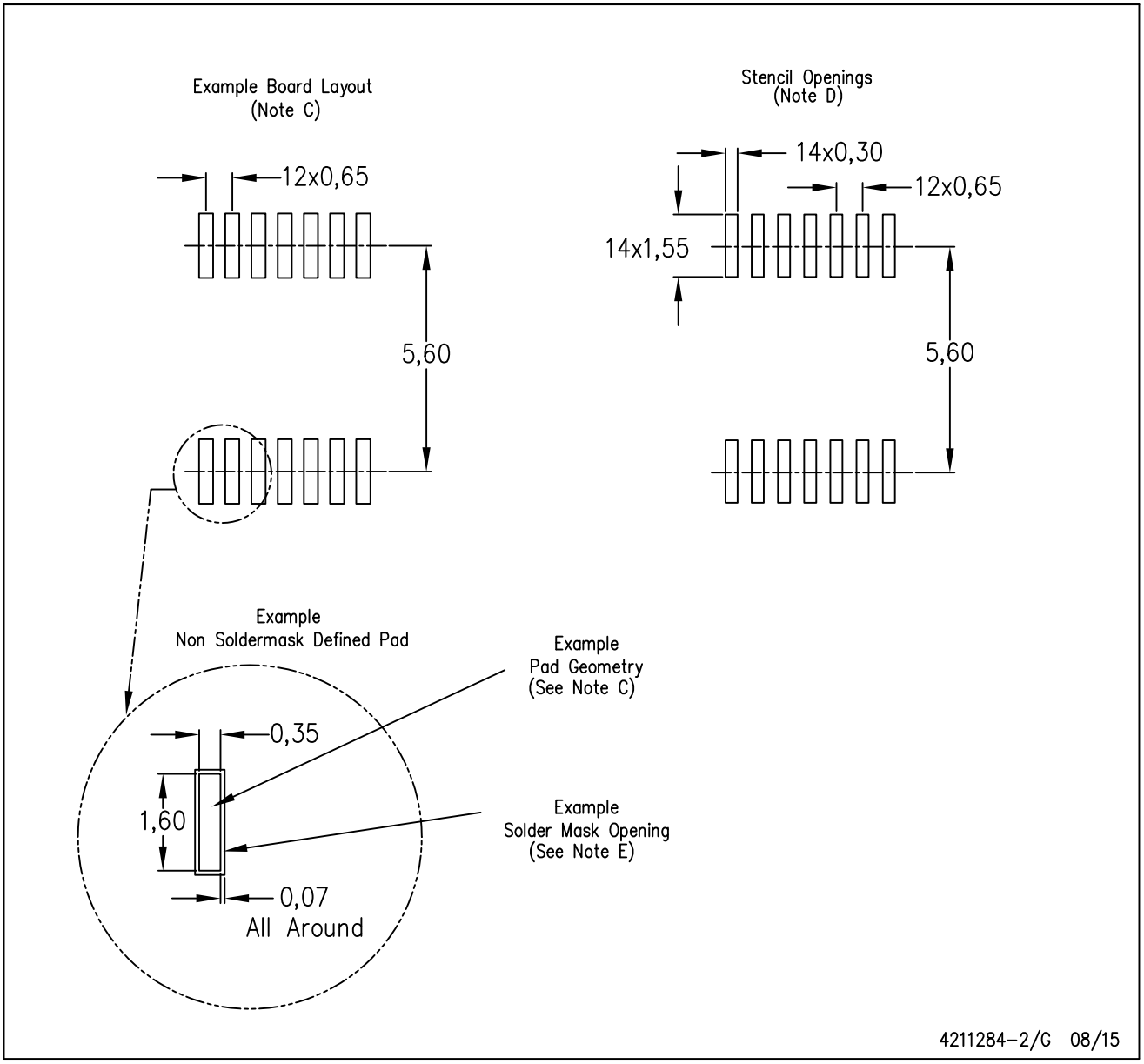
PW (R–PDSO–G14) PLASTIC SMALL OUTLINE



4040064–3/G 02/11

NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
E. Falls within JEDEC MO–153

PW (R–PDSO–G14) PLASTIC SMALL OUTLINE

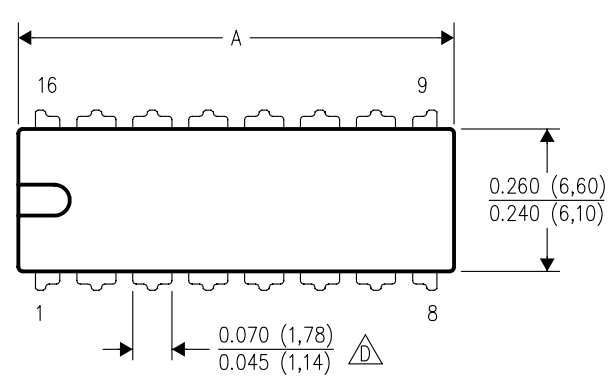


NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

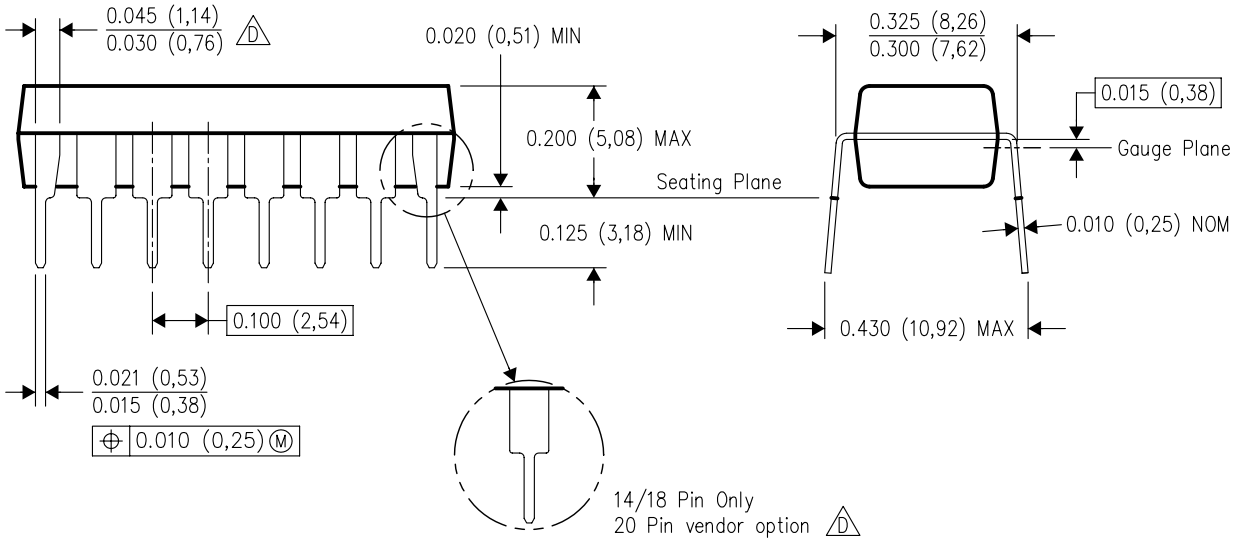
N (R–PDIP–T**)

PLASTIC DUAL–IN–LINE PACKAGE

16 PINS SHOWN



DIM \ PINS **	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS–001 VARIATION (C)	AA	BB	AC	AD



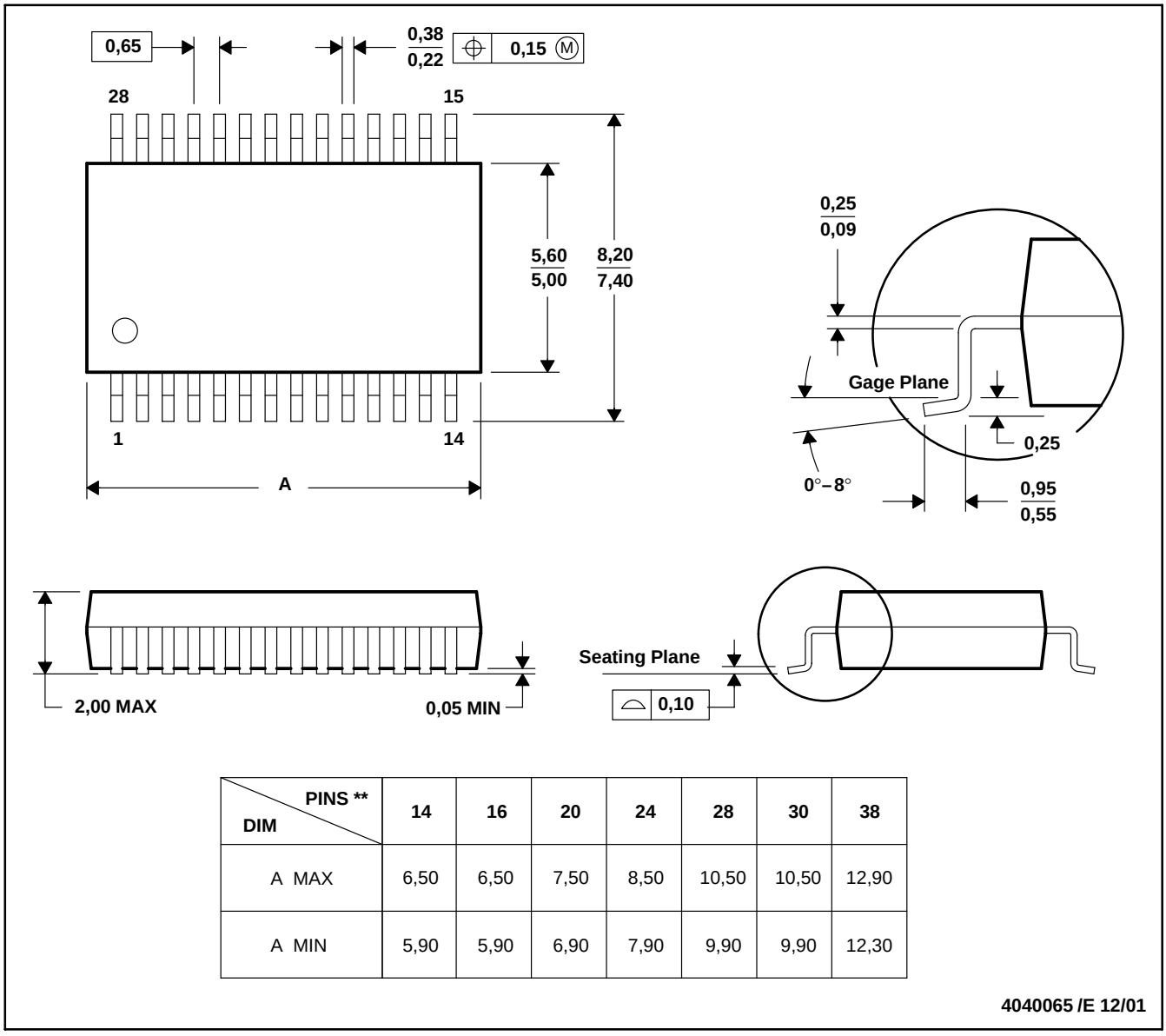
4040049/E 12/2002

NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS–001, except 18 and 20 pin minimum body length (Dim A).
D. The 20 pin end lead shoulder width is a vendor option, either half or full width.

MSSO002E – JANUARY 1995 – REVISED DECEMBER 2001

DB (R-PDSO-G)** **PLASTIC SMALL-OUTLINE**

28 PINS SHOWN



DIM \ PINS **	14	16	20	24	28	30	38
A MAX	6,50	6,50	7,50	8,50	10,50	10,50	12,90
A MIN	5,90	5,90	6,90	7,90	9,90	9,90	12,30

4040065 /E 12/01

NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
D. Falls within JEDEC MO-150

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